

PIC24FJ256GA412/GB412 Family Flash Programming Specification

1.0 DEVICE OVERVIEW

This document defines the programming specification for the PIC24FJ256GA412/GB412 family of 16-bit microcontrollers with Dual Partition Flash mode functionality. This programming specification is required only for those developing programming support for the following devices:

- PIC24FJ256GB412
- PIC24FJ256GA412
- PIC24FJ128GB412
- PIC24FJ128GA412
- PIC24FJ64GB412
- PIC24FJ64GA412
- PIC24FJ256GB410
- PIC24FJ256GA410
- PIC24FJ128GB410
- PIC24FJ128GA410
- PIC24FJ64GB410
- PIC24FJ64GA410
- PIC24FJ256GB406
- PIC24FJ256GA406
- PIC24FJ128GB406
- PIC24FJ128GA406
- PIC24FJ64GB406
- PIC24FJ64GA406

Customers using only one of these devices should use the development tools that already provide support for device programming. Topics covered include:

- Section 1.0 "Device Overview"
- Section 2.0 "Programming Overview"
- Section 3.0 "Device Programming ICSP"
- Section 4.0 "Device Programming Enhanced ICSP"
- Section 5.0 "Programming the Programming Executive to Memory"
- Section 6.0 "The Programming Executive"
- Section 7.0 "Dual Partition Flash Programming Considerations"
- Section 8.0 "Device ID"
- Section 9.0 "Checksum Computation"
- Section 10.0 "AC/DC Characteristics and Timing Requirements"

2.0 PROGRAMMING OVERVIEW

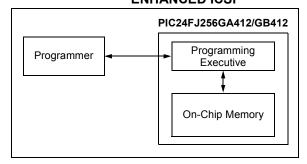
There are two methods of programming that are discussed in this programming specification:

- In-Circuit Serial Programming™ (ICSP™)
- · Enhanced In-Circuit Serial Programming

The ICSP programming method is the most direct method to program the device; however, it is also the slower of the two methods. It provides native, low-level programming capability to erase, program and verify the device.

The Enhanced ICSP protocol uses a faster method that takes advantage of the Programming Executive (PE), as illustrated in Figure 2-1. The PE provides all the necessary functionality to erase, program and verify the chip through a small command set. The command set allows the programmer to program a PIC24FJ256GA412/GB412 family device without dealing with the low-level programming protocols.

FIGURE 2-1: PROGRAMMING SYSTEM OVERVIEW FOR ENHANCED ICSP™



This programming specification is divided into two major sections that describe the programming methods independently. Section 3.0 "Device Programming – ICSP" describes the ICSP method. Section 4.0 "Device Programming – Enhanced ICSP" describes the Enhanced ICSP method.

2.1 Required Connections

These devices require specific connections for programming to take place. These connections include power, VcAP, MCLR and one programming pair (PGEDx/PGECx). Table 2-1 describes these connections (refer to the specific device data sheet for pin descriptions and power connection requirements).

2.2 Power Requirements

All PIC24FJ256GA412/GB412 family devices power their core digital logic at a nominal 1.8V. To simplify system design, all devices in the PIC24FJ256GA412/GB412 family incorporate an on-chip regulator that allows the device to run its core logic from VDD.

The regulator provides power to the core from the other VDD pins. A low-ESR capacitor (such as ceramic or tantalum) must be connected to the VCAP pin (see Table 2-1 and Figure 2-2). This helps to maintain the stability of the regulator. The specifications for core voltage and capacitance are listed in Section 10.0 "AC/DC Characteristics and Timing Requirements".

FIGURE 2-2: CONNECTIONS FOR THE ON-CHIP REGULATOR

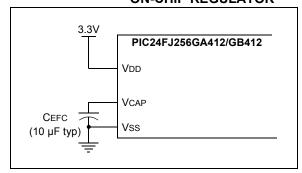


TABLE 2-1: PINS USED DURING PROGRAMMING

Pin Name	Pin Type	Pin Description						
MCLR	I	Programming Enable						
VDD and AVDD ⁽¹⁾	Р	Power Supply ⁽¹⁾						
Vss and AVss ⁽¹⁾	Р	Ground ⁽¹⁾						
VCAP	Р	On-Chip Voltage Regulator Filter Capacitor						
PGECx	1	Programming Pin Pair: Serial Clock						
PGEDx	I/O	Programming Pin Pair: Serial Data						

Legend: I = Input O = Output P = Power

Note 1: All power supply and ground pins must be connected, including AVDD and AVSS. It is also recommended to connect the VBAT pin to the battery or VDD during programming.

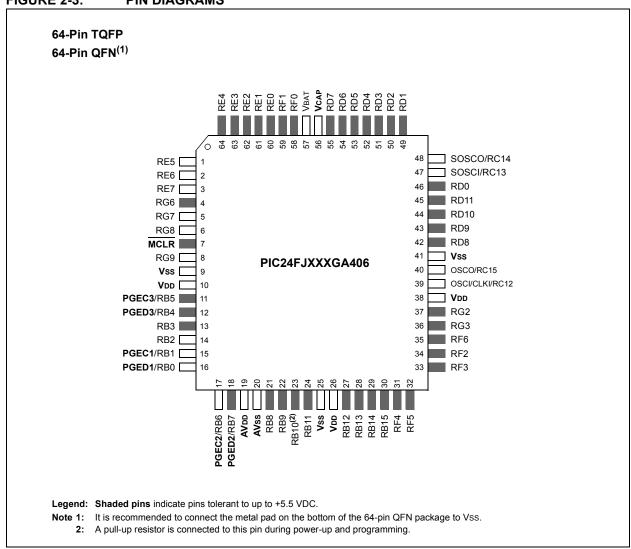
2.3 Pin Diagrams

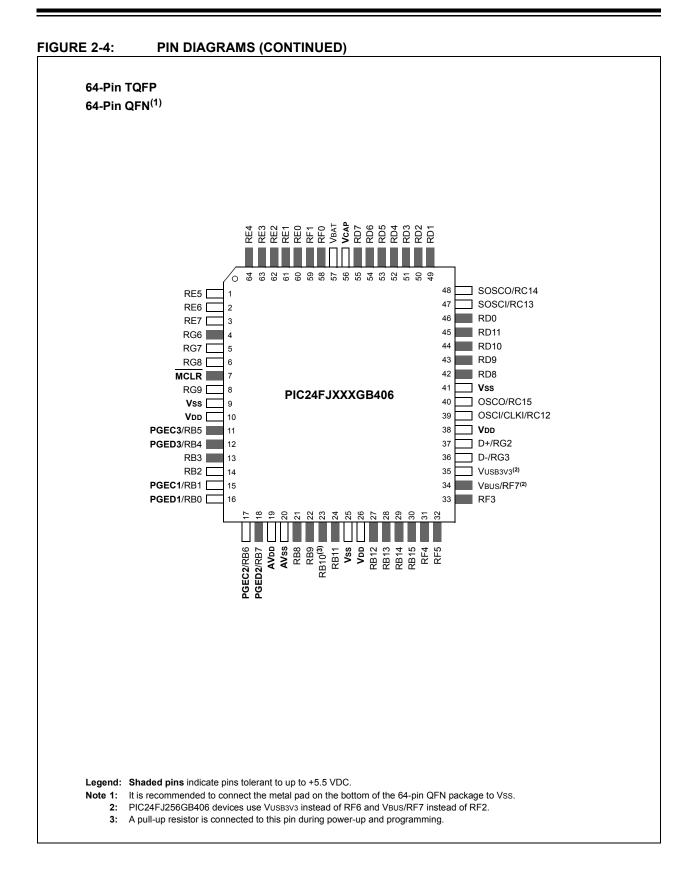
Figure 2-3 through Figure 2-7 show the pin diagrams for the PIC24FJ256GA412/GB412 family. The pins that are required for programming are listed in Table 2-1 and are indicated in bold text in the figures. Refer to the appropriate device data sheet for complete pin descriptions.

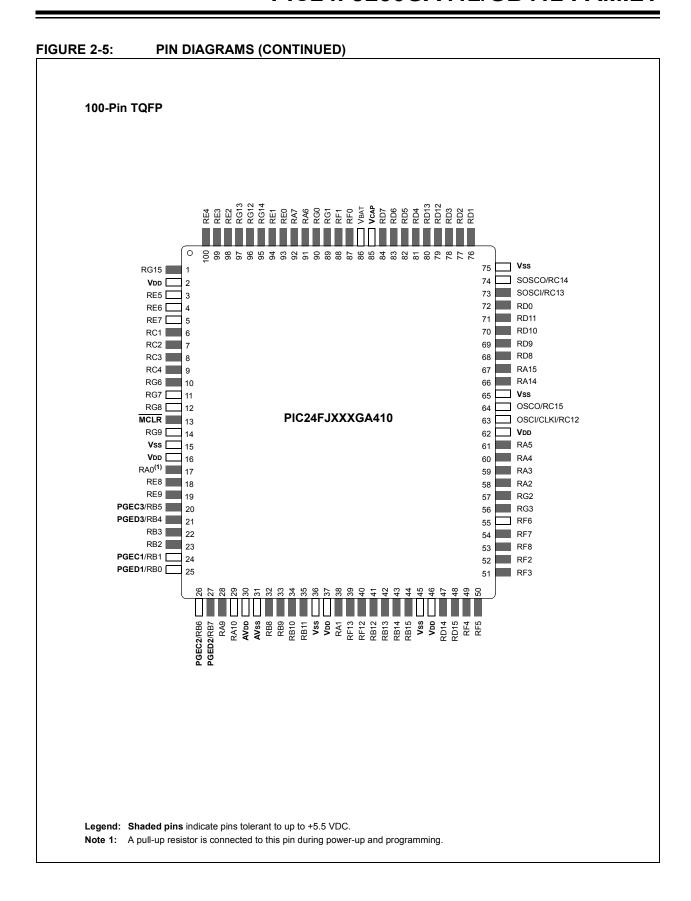
2.3.1 PGECx AND PGEDx PIN PAIRS

All devices in the PIC24FJ256GA412/GB412 family have three separate pairs of programming pins, labeled as PGEC1/PGED1, PGEC2/PGED2 and PGEC3/PGED3. Any one of these pin pairs may be used for device programming by either ICSP or Enhanced ICSP. Unlike voltage supply and ground pins, it is not necessary to connect all three pin pairs to program the device. However, the programming method must use both pins of the same pair.









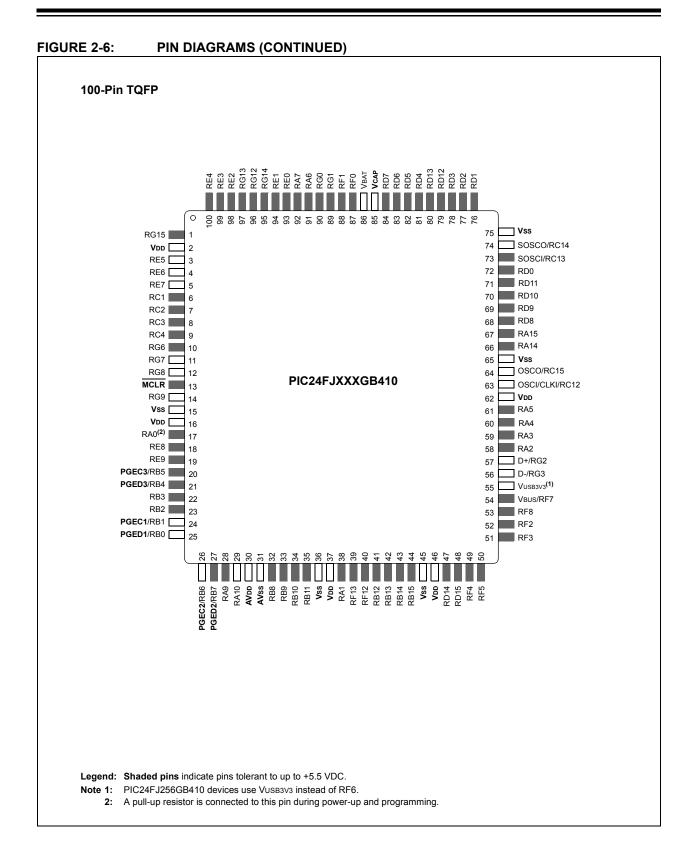


FIGURE 2-7: **PIN DIAGRAMS (CONTINUED)** PIC24FJXXXGA412, 121-Pin TFBGA 2 10 1 3 4 5 6 7 8 9 11 \bigcirc RE4 RE3 RG13 RE0 RG0 RF1 VBAT RH14 RD12 RD2 RD1 Α \bigcirc \bigcirc ()В RH1 RG15 RE2 RE1 RA7 RF0 VCAP RD5 RD3 Vss RC14 С RE6 VDD RG12 RG14 RA6 Vss RD7 RD4 RH13 RC13 RD11 \bigcirc \bigcirc \bigcirc \bigcirc D RC1 VDD RD6 RD13 RD0 RD10 \bigcirc Ε RC4 RG1 RA15 RD8 RD9 RA14 \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc F MCLR RG8 RG9 RG7 Vss RH15 RH12 VDD OSCI/RC12 Vss OSCO/RC15 \bigcirc \bigcirc G RE8 RE9 RA0⁽¹⁾ RH3 RH11 RA5 RA3 RA4 VDD Vss Vss \bigcirc \bigcirc Н PGEC3/RB5 PGED3/RB4 RH5 RB10 VDD RH8 RF6 RG2 RA2 \bigcirc \bigcirc \bigcirc J RB3 RB2 PGED2/RB7 RH7 RA1 RB12 RH9 RH10 RF8 RG3 \bigcirc \bigcirc \bigcirc Κ PGEC1/RB1 PGED1/RB0 RA10 RF12 RB8 RB11 RB14 VDD RD15 RF3 RF2 \bigcirc \bigcirc \bigcirc L PGEC2/RB6 RA9 RB9 RH6 RF13 RB13 RB15 RD14 RF4 RF5 **AV**ss Legend: Shaded balls indicate pins tolerant to up to +5.5 VDC. Note 1: A pull-up resistor is connected to this pin during power-up and programming.

FIGURE 2-8: PIN DIAGRAMS (CONTINUED)

	1	2	3	4	5	6	7	8	9	10	11
	RE4	RE3	RG13	RE0	RG0	RF1	VBAT	RH14	RD12	RD2	RD1
,	RH1	RG15	RE2	RE1	RA7	RF0	VCAP	RD5	RD3	O Vss	C RC14
;	C RE6	V _{DD}	RG12	RG14	RA6	Vss	RD7	RD4	RH13	C RC13	RD11
	RC1	C RE7	C RE5	RH2	RJ0	V _{DD}	RD6	RD13	RD0	Vss	RD10
	RC4	RC3	RG6	RC2	RJ1	RG1	V _{DD}	RA15	RD8	RD9	RA14
	MCLR	RG8	RG9	O RG7	○ Vss	C RH15	RH12	VDD	OSCI/RC12	○ Vss	OSCO/RC15
i	RE8	RE9	RA0 ⁽²⁾	RH3	VDD	Vss	○ Vss	RH11	RA5	RA3	RA4
	PGEC3/RB5	PGED3/RB4	C RH4	RH5	RB10	VDD	RH8	VBUS/RF7	VUSB3V3 ⁽¹⁾	D+/RG2	RA2
	RB3	RB2 P	GED2/RB7	AVDD	C RH7	RA1	RB12	RH9	C RH10	RF8	D-/RG3
	PGEC1/RB1 F	PGED1/RB0	C RA10	RB8	RB11	RF12	RB14	VDD	RD15	RF3	RF2
i	PGEC2/RB6	C RA9	O AVss	RB9	RH6	RF13	RB13	RB15	RD14	RF4	RF5

 $\textbf{Legend:} \ \ \textbf{Shaded balls} \ \text{indicate pins tolerant to up to +5.5 VDC}.$

Note 1: PIC24FJ256GB412 devices use VUSB3V3 instead of RF6.

2: A pull-up resistor is connected to this pin during power-up and programming.

2.4 Program Memory Write/Erase Requirements

The Program Flash Memory (PFM) has a specific write/ erase requirement that must be adhered to for proper device operation. The rule is that any given word in memory must not be written without first erasing the page in which it is located. Thus, the easiest way to conform to this rule is to write all the data in a programming block within one write cycle. The programming methods specified in this document comply with this requirement.

2.5 Memory Map

The program memory map extends from 0x00 0000 to 0xFF FFFE. Code storage is located at the base of the memory map. The last locations of implemented program memory are reserved for the device Configuration bits.

Table 2-2 lists the code memory size, the size of the erase blocks and the number of erase blocks present in each device variant.

Locations, 0x80 0100 through 0x80 0BFE, are reserved for executive code memory. This region stores the PE and the debugging executive, which is used for device programming. This region of memory cannot be used to store user code. See Section 6.0 "The Programming Executive" for more information.

Locations, 0x80 1380 through 0x80 13FE, are reserved for the customer OTP data. This area can be used for storing product information, such as serial numbers, system manufacturing dates, manufacturing lot numbers and other application-specific information; it is described in Section 2.6.3 "One-Time-Programmable (OTP) Memory".

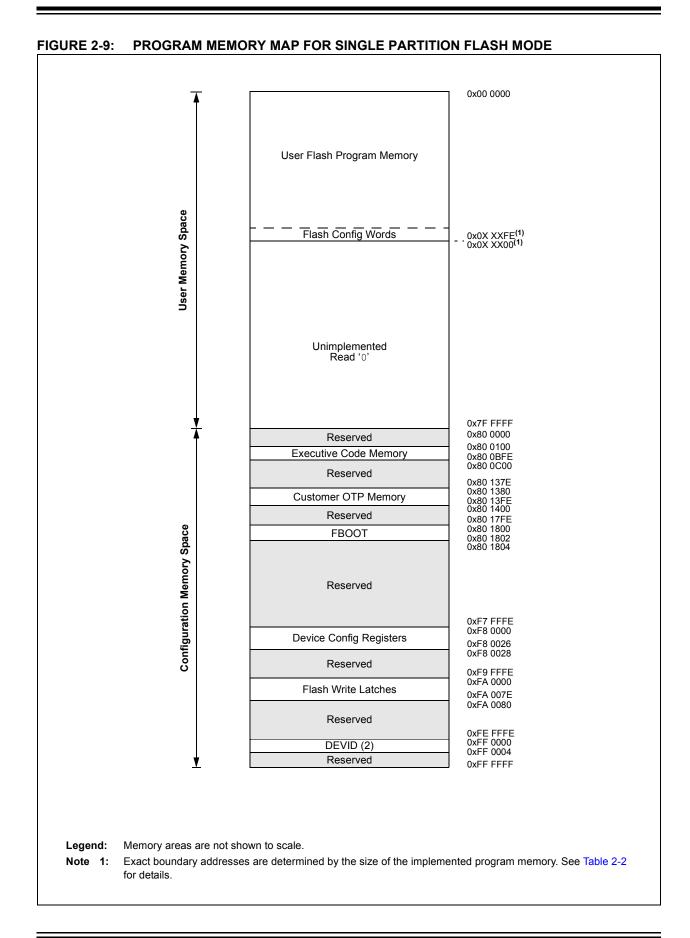
Locations, 0xFF 0000 and 0xFF 0002, are reserved for the Device ID Word registers. These bits can be used by the programmer to identify which device type is being programmed. They are described in **Section 8.0** "Device ID". The Device ID registers read out normally, even after code protection is applied.

Figure 2-9 and Figure 2-10 show the generic memory maps for the devices described in this specification. See the "Memory Organization" chapter in the specific device data sheet for exact memory addresses.

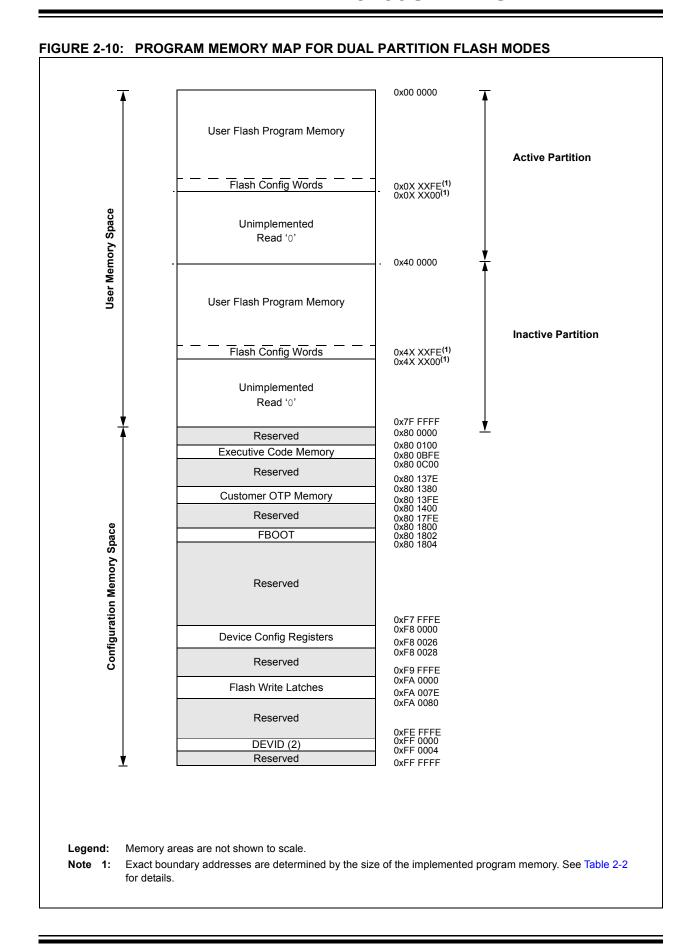
TABLE 2-2: PROGRAM MEMORY SIZES AND BOUNDARIES

	Program Memory	/ Upper Boundary (I				
Device	Single Partition	Dual Partition	n Flash Mode	Write Blocks ⁽¹⁾	Erase Blocks ⁽¹⁾	
	Flash Mode	Active Partition	ive Partition Inactive Partition			
PIC24FJ256GX4XX	0x02 AFFE (86K)	0x01 57FE (43K)	0x41 57FE (43K)	1376	172	
PIC24FJ128GX4XX	0x01 57FE (43K)	0x00 ABFE (22K)	0x40 ABFE (22K)	688	86	
PIC24FJ64GX4XX	0x00 AFFE (22K)	0x00 57FE (11K)	0x40 57FE (11K)	352	44	

Note 1: 1 Write Block = 64 Instruction Words; 1 Erase Block = 512 Instruction Words.



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2.6 Configuration Bits

2.6.1 OVERVIEW

The Configuration bits are stored in the last page location of implemented program memory. These bits can be set or cleared to select various device configurations. There are two types of Configuration bits: system operation bits and code-protect bits. The system operation bits determine the power-on settings for system-level components, such as the oscillator and the Watchdog Timer. The code-protect bits prevent program memory from being read and written.

Table 2-3 lists the Configuration register address range for each device in Single and Dual Partition modes. Table 2-4 lists all of the Configuration bits found in the PIC24FJ256GA412/GB412 family devices, as well as their Configuration register locations. Refer to the "Special Features" chapter in the specific device data sheet for the full Configuration register description for a specific device.

2.6.2 CODE-PROTECT CONFIGURATION BITS

The device implements an intermediate security feature defined by the FSEC register. The Boot Segment (BS) is the higher privilege segment and the General Segment (GS) is the lower privilege segment. The total user code memory can be split into BS or GS. The size of the segments is determined by the BSLIM[12:0] bits. The relative location of the segments within user space does not change, such that BS (if present) occupies the memory area just after the Interrupt Vector Table (IVT) and the GS occupies the space just after the BS (or if the Alternate IVT is enabled, just after it).

The Configuration Segment (or CS) is a small segment (less than a page, typically just one row) within user Flash address space. It contains all user configuration data that is loaded by the NVM Controller during the Reset sequence.

TABLE 2-3: CONFIGURATION WORD ADDRESSES

Configuration	Single Partition Flash Mode									
Register	PIC24FJ256GX4XX	PIC24FJ128GX4XX	PIC24FJ64GX4XX							
FSEC	0x02 AF80	0x01 5780	0x00 AF80							
FBSLIM	0x02 AF90	0x01 5790	0x00 AF90							
FSIGN	0x02 AF94	0x01 5794	0x00 AF94							
FOSCSEL	0x02 AF98	0x01 5798	0x00 AF98							
FOSC	0x02 AF9C	0x01 579C	0x00 AF9C							
FWDT	0x02 AFA0	0x01 57A0	0x00 AFA0							
FPOR	0x02 AFA4	0x01 57A4	0x00 AFA4							
FICD	0x02 AFA8	0x01 57A8	0x00 AFA8							
FDS	0x02 AFAC	0x01 57AC	0x00 AFAC							
FDEVOPT1	0x02 AFB0 0x01 57B0		0x00 AFB0							
FBOOT	0x80 1800									
		Dual Partition Flash Modes ⁽¹⁾								
FSEC ⁽²⁾	0x01 5780/0x41 5780	0x00 AB80/0x40 AB80	0x00 5780/0x40 5780							
FBSLIM ⁽²⁾	0x01 5790/0x41 5790	0x00 AB90/0x40 AB90	0x00 5790/0x40 5790							
FSIGN ⁽²⁾	0x01 5794/0x41 5794	0x00 AB94/0x40 AB94	0x00 5794/0x40 5794							
FOSCSEL	0x01 5798/0x41 5798	0x00 AB98/0x40 AB98	0x00 5798/0x40 5598							
FOSC	0x01 579C/0x41 579C	0x00 AB9C/0x40 AB9C	0x00 559C/0x40 579C							
FWDT	0x01 57A0/0x41 57A0	0x00 ABA0/0x40 ABA0	0x00 57A0/0x40 57A0							
FPOR	0x01 57A4/0x41 57A4	0x00 ABA4/0x40 ABA4	0x00 57A4/0x40 57A4							
FICD	0x01 57A8/0x41 57A8	0x00 ABA8/0x40 ABA8	0x00 57A8/0x40 57A8							
FDS	0x01 57AC/0x41 57AC	0x00 ABAC/0x40 ABAC	0x00 57AC/0x40 57AC							
FDEVOPT1	0x01 57B0/0x41 57B0	0x00 ABB0/0x40 ABB0	0x00 57B0/0x40 57B0							
FBTSEQ	0x01 57FC/0x41 57FC	0x00 ABFC/0x40 ABFC	0x00 57FC/0x40 57FC							
FBOOT		0x80 1800								

Note 1: Addresses shown for Dual Partition Flash modes are for the Active/Inactive Partitions, respectively.

^{2:} Changes to these Inactive Partition Configuration Words affect how the Active Partition accesses the Inactive Partition.

TABLE 2-4: CONFIGURATION REGISTERS MAP

Register Name	Bits 23-16	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
FSEC	_	AIVTDIS	_	_	_		CSS[2:0]		CWRP	GSS	[1:0]	GWRP	_		BSS[2:0]		BWRP
FBSLIM	_	_	-	ı							BSLIM[1	12:0]					
FSIGN	_	SIGN	-	_	_	_	_	-	_	_	_	_	_	_	-	-	_
FOSCSEL	_	-	-	_	_	_	_	-	_	IESO	IESO PLLMODE[3:0]			FNOSC[2:0]			
FOSC	_	-	-	_	_	_	_	-	_	FCKS	M[1:0]	IOL1WAY	PLLSS	SOSCSEL	OSCIOFNC	POSC	MD[1:0]
FWDT	_	-	WDTC	CLK[1:0]	_	WDTCMX	_	WDTV	VIN[1:0]	WINDIS	FWD'	TEN[1:0]	WDTPRE		WDTPS[3	3:0]	
FPOR	_	-	-	_	_	_	_	-	_	r ⁽¹⁾	_	_	_	_	RETVRDIS	BORE	N[1:0]
FICD	_	NOBTSWP	-	_	_	_	_	-	_	BKBUG	_	JTAGEN	_	_	-	ICS[[1:0]
FDS	_	DSBITEN	_	_	_	_	_	_	_	DSWDTEN	DSZPBOR	DSWDTLPRC		DSWDTPS[4:0]			
FDEVOPT1	_	_	_	_	_	_	_	_	_	_	_	_	_		DOPT[3:1]		_
FBTSEQ			IBSEQ[11:	0]						•	BS	SEQ[11:0]					
FBOOT	_	_	-	ı	_	_	_	-	1	_	_	_	_	_	_	BTMOI	DE[1:0]

Legend: — = unimplemented bit, read as '1'. **Note 1:** Bit is reserved, maintain as '0'.

2.6.3 ONE-TIME-PROGRAMMABLE (OTP) MEMORY

PIC24FJ256GA412/GB412 family devices provide 384 bytes of One-Time Programmable (OTP) memory, located at addresses, 0x80 1700 through 0x80 17FE. This memory can be used for persistent storage of application-specific information that will not be erased by reprogramming the device. This includes many types of information, such as (but not limited to):

- · Application checksums
- · Code revision information
- · Product information
- · Serial numbers
- · System manufacturing dates
- · Manufacturing lot numbers

Customer OTP memory may be programmed in any mode, including user RTSP mode, but it cannot be erased. Data is not cleared by a Chip Erase.

Do not perform repeated writes on the OTP memory.

3.0 DEVICE PROGRAMMING - ICSP

ICSP mode is a special programming protocol that allows you to read and write to device memory. The ICSP mode is the most direct method used to program the device, which is accomplished by applying control codes and instructions serially to the device, using the PGECx and PGEDx pins. ICSP mode also has the ability to read executive memory to determine if the Programming Executive (PE) is present and to write the PE to executive memory if Enhanced ICSP mode will be used.

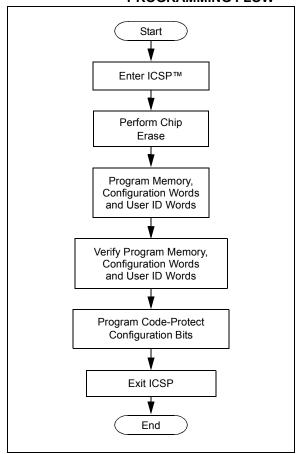
In ICSP mode, the system clock is taken from the PGECx pin, regardless of the device's Oscillator Configuration bits. All instructions are shifted serially into an internal buffer, then loaded into the Instruction Register (IR) and executed. No program fetching occurs from internal memory. Instructions are fed in 24 bits at a time. PGEDx is used to shift data in, and PGECx is used as both the serial shift clock and the CPU execution clock.

- **Note 1:** During ICSP operation, the operating frequency of PGECx must not exceed 5 MHz.
 - **2:** ICSP mode is slower than Enhanced ICSP mode for programming.

3.1 Overview of the Programming Process

Figure 3-1 illustrates the high-level overview of the programming process. After entering ICSP mode, the first action is to Chip Erase program memory. Next, the code memory is programmed, followed by the device Configuration bits. Code memory (including the Configuration bits) is then verified to ensure that programming was successful. Then, the code-protect Configuration bits are programmed, if required.

FIGURE 3-1: HIGH-LEVEL ICSP™
PROGRAMMING FLOW



3.2 Entering ICSP Mode

As illustrated in Figure 3-2, entering ICSP Program/ Verify mode requires three steps:

- MCLR is briefly driven high and then low (P21).⁽¹⁾
- 2. A 32-bit key sequence is clocked into PGEDx.
- 3. MCLR is then driven high within a specified period of time, 'P19', and held.

Note 1: If a capacitor is present on the MCLR pin, the high time for entering ICSP mode can vary.

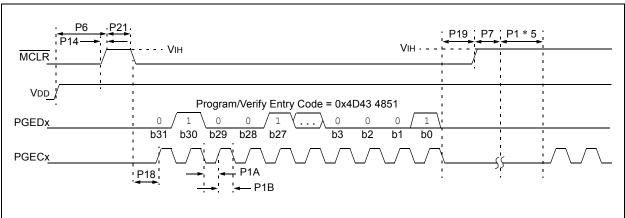
The programming voltage applied to MCLR is VIH, which is essentially VDD in the case of PIC24FJ256GA412/GB412 family devices. There is no minimum time requirement for holding at VIH. After VIH is removed, an interval of at least P18 must elapse before presenting the key sequence on PGEDx.

The key sequence is a specific 32-bit pattern, '0100 1101 0100 0011 0100 1000 0101 0001' (more easily remembered as 0x4D43 4851 in hexadecimal). The device will enter Program/Verify mode only if the sequence is valid. The Most Significant bit (MSb) of the most significant nibble must be shifted in first.

Once the key sequence is complete, VIH must be applied to MCLR and held at that level for as long as Program/Verify mode is to be maintained. An interval time of at least P19, P7 and P1 * 5 must elapse before presenting data on PGEDx. Signals appearing on PGEDx before P7 has elapsed will not be interpreted as valid.

On successful entry, the program memory can be accessed and programmed in serial fashion. While in ICSP mode, all unused I/Os are placed in a high-impedance state.

FIGURE 3-2: ENTERING ICSP™ MODE



3.3 ICSP Operation

After entering into ICSP mode, the CPU is Idle. Execution of the CPU is governed by an internal state machine. A 4-bit control code is clocked in using PGECx and PGEDx, and this control code is used to command the CPU (see Table 3-1).

The SIX control code is used to send instructions to the CPU for execution and the REGOUT control code is used to read data out of the device through the VISI register.

TABLE 3-1: CPU CONTROL CODES IN ICSP™ MODE

4-Bit Control Code	Mnemonic	Description
0000	SIX	Shift in 24-bit instruction and execute.
0001	REGOUT	Shift out the VISI register.
0010-1111	N/A	Reserved.

3.3.1 SIX SERIAL INSTRUCTION EXECUTION

The SIX control code allows execution of assembly instructions. When the SIX code is received, the CPU is suspended for 24 clock cycles as the instruction is then clocked into the internal buffer. Once the instruction is shifted in, the state machine allows it to be executed over the next four clock cycles. While the received instruction is executed, the state machine simultaneously shifts in the next 4-bit command (see Figure 3-3).

- Note 1: Coming out of the ICSP entry sequence, the first 4-bit control code is always forced to SIX and a forced NOP instruction is executed by the CPU. Five additional PGECx clocks are needed on start-up, thereby resulting in a 9-bit SIX command instead of the normal 4-bit SIX command. After the forced SIX is clocked in, ICSP operation resumes as normal (the next 24 clock cycles load the first instruction word to the CPU). See Figure 3-4 for details.
 - TBLRDH, TBLRDL, TBLWTH and TBLWTL instructions must be followed by a NOP instruction.

FIGURE 3-3: SIX SERIAL EXECUTION

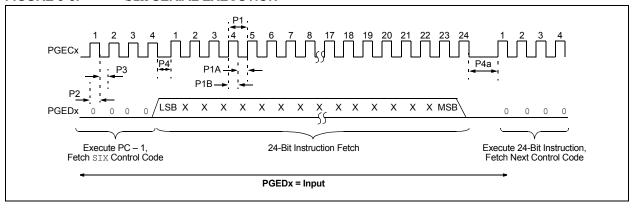
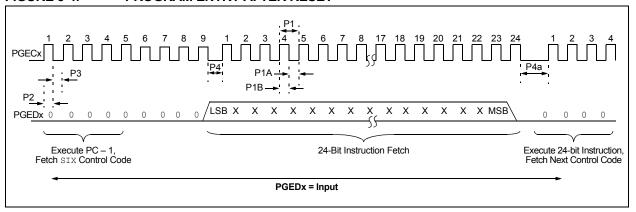


FIGURE 3-4: PROGRAM ENTRY AFTER RESET



3.3.2 REGOUT SERIAL INSTRUCTION **EXECUTION**

The REGOUT control code allows for data to be extracted from the device in ICSP mode. It is used to clock the contents of the VISI register out of the device over the PGEDx pin. After the REGOUT control code is received, the CPU is held Idle for eight cycles. After these eight cycles, an additional 16 cycles are required to clock the data out (see Figure 3-5).

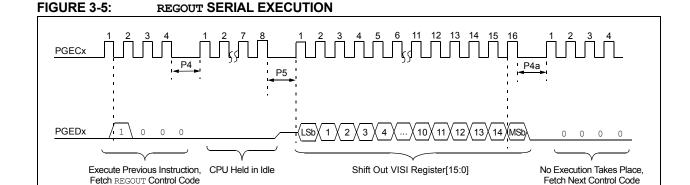
PGEDx = Input

The REGOUT code is unique because the PGEDx pin is an input when the control code is transmitted to the device. However, after the control code is processed, the PGEDx pin becomes an output as the VISI register is shifted out.

Note: The device will latch input PGEDx data on

the rising edge of PGECx and will output data on the PGEDx line on the rising edge of PGECx. For all data transmissions, the Least Significant bit (LSb) is transmitted first.

PGEDx = Input



PGEDx = Output

3.4 Flash Memory Programming in ICSP Mode

3.4.1 PROGRAMMING OPERATIONS

Flash memory write/erase operations are controlled by the NVMCON register. Programming is performed by setting NVMCON to select the type of erase operation (Table 3-2) or write operation (Table 3-3) and initiating the programming by setting the WR control bit (NVMCON[15]).

In ICSP mode, all programming operations are self-timed. There is an internal delay between the user setting the WR control bit and the automatic clearing of the WR control bit when the programming operation is complete. Refer to Section 10.0 "AC/DC Characteristics and Timing Requirements" for detailed information about the delays associated with various programming operations.

TABLE 3-2: NVMCON ERASE OPERATIONS

NVMCON Value	Erase Operation
0x400E	Chip Erase user memory (does not erase Device ID, customer OTP or Program Executive memory).
0x4003	Erase a page of program or executive memory.
0x4004	Erase user memory and Configuration Words in the Inactive Partition (Dual Partition modes only).

TABLE 3-3: NVMCON WRITE OPERATIONS

NVMCON Value	Write Operation
0x4001	Double-word program operation.
0x4002	Row programming operation.

3.4.2 STARTING AND STOPPING A PROGRAMMING CYCLE

For protection against accidental operations, the erase/write initiate sequence must be written to the NVMKEY register to allow any erase or program operation to proceed. The two instructions following the start of the programming sequence should be NOPS. To start an erase or write sequence, the following steps must be completed:

- 1. Write 0x55 to the NVMKEY register.
- Write 0xAA to the NVMKEY register.
- 3. Set the WR bit in the NVMCON register.
- 4. Execute three NOP instructions.

All erase and write cycles are self-timed. The WR bit should be polled to determine if the erase or write cycle has been completed.

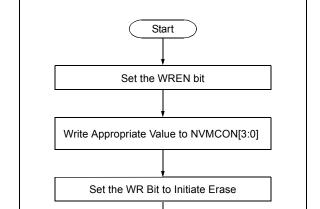
3.5 Erasing Program Memory

The general procedure for erasing user memory is shown in Figure 3-6. The process for Chip Erase, Page Erase and Inactive Partition Erase are all substantially similar, and are described in Table 3-4 through Table 3-6.

The last row of the last page of program memory contains the Flash Configuration Words. Before programming these Words, they must be erased. If they are erased with a Page Erase operation, all other rows in the page will also be erased. Users may want to either avoid using the rest of this page for application code, or ensure that the non-configuration data in the CS page is copied before the erase and reprogrammed afterwards.

The Configuration Read registers can only be loaded as part of the Reset sequence and cannot be modified at any other time.

- **Note 1:** Program memory must be erased before writing any data to program memory.
 - 2: For Page Erase operations, the NVMADRL/H registers must also be loaded with the address of the page to be erased.



Delay P11 + P10 Time

End

ERASE FLOW

FIGURE 3-6:

TABLE 3-4: SERIAL EXECUTION FOR CHIP ERASE

Command (Binary)	Data (Hex)		Description							
Step 1: Exit the R	Step 1: Exit the Reset vector.									
0000	000000	NOP								
0000	040200	GOTO	0x200							
0000	000000	NOP								
Step 2: Configure	the NVMCON re	gister to pe	rform a Chip Erase.							
0000	2400E0	MOV	#0x400E, W0							
0000	883B00	MOV	WO, NVMCON							
Step 3: Set the W	Step 3: Set the WR bit.									
0000	200550	MOV	#0x55, W0							
0000	883B30	MOV	WO, NVMKEY							
0000	200AA0	MOV	#0xAA, W0							
0000	883B30	MOV	WO, NVMKEY							
0000	A8E761	BSET	NVMCON, #WR							
0000	000000	NOP								
0000	000000	NOP								
0000	000000	NOP								
Step 4: Repeat th	is step to poll the	WR bit unti	l it is cleared by hardware.							
0000	040200	GOTO	0x200							
0000	00000	NOP								
0000	803B02	MOV	NVMCON, W2							
0000	883C22	MOV	W2, VISI							
0000	000000	NOP								
0001	<visi></visi>	Clock out	the contents of the VISI register.							
0000	000000	NOP	-							
0000	060000	RETURN								

TABLE 3-5: SERIAL EXECUTION FOR PAGE ERASE

Command (Binary)	Data (Hex)		Description						
Step 1: Exit the F	Step 1: Exit the Reset vector.								
0000	000000	NOP							
0000	040200	GOTO	0x200						
0000	000000	NOP							
Step 2: Set the N	IVMCON register to	erase a	a page.						
0000	240030	MOV	#0x4003, W0						
0000	883B00	MOV	WO, NVMCON						
Step 3: Load the	address of the pag	e to be e	erased into the NVMADR register pair.						
0000	200000	MOV	#PageAddress<15:0>, W0						
0000	883B10	MOV	WO, NVMADR						
0000	200000	MOV	<pre>#PageAddress<24:16>, W0</pre>						
0000	883B20	MOV	WO, NVMADRU						
Step 4: Set the V	VR bit.								
0000	200550	MOV	#0x55, W0						
0000	883B30	MOV	WO, NVMKEY						
0000	200AA0	MOV	#OxAA, WO						
0000	883B30	MOV	WO, NVMKEY						
0000	A8E761	BSET	NVMCON, #WR						
0000	000000	NOP							
0000	000000	NOP							
0000	000000	NOP							
Step 5: Repeat th	his step to poll the V	VR bit u	ntil it is cleared by hardware.						
0000	040200	GOTO	0x200						
0000	000000	NOP							
0000	803B02	MOV	NVMCON, W2						
0000	883C22	MOV	W2, VISI						
0000	000000	NOP							
0001	<visi></visi>	Clock o	out the contents of the VISI register.						
0000	000000	NOP							
Step 6: Clear the	WREN bit.								
0000	200000	MOV	NVMCON, W2						
0000	883B00	MOV	WO, NVMCON						

TABLE 3-6: SERIAL EXECUTION FOR INACTIVE PARTITION ERASE

IABLE 3-6.	SLINIAL EXECU	I ION F	OR INACTIVE PARTITION ERASE					
Command (Binary)	Data (Hex)		Description					
Step 1: Exit the Reset vector.								
0000	000000	NOP						
0000	040200	GOTO	0x200					
0000	000000	NOP						
Step 2: Set the N	NVMCON register t	o erase a	a page.					
0000	240040	MOV	#0x4004, W0					
0000	883B00	MOV	WO, NVMCON					
Step 3: Set the V	VR bit.							
0000	200550	MOV	#0x55, WO					
0000	883B30	MOV	WO, NVMKEY					
0000	200AA0	MOV	#0xAA, W0					
0000	883B30	MOV	WO, NVMKEY					
0000	A8E761	BSET	NVMCON, #WR					
0000	000000	NOP						
0000	000000	NOP						
0000	000000	NOP						
Step 4: Repeat to	his step to poll the	WR bit u	ıntil it is cleared by hardware.					
0000	040200	GOTO	0x200					
0000	000000	NOP						
0000	803B02	VOM	NVMCON, W2					
0000	883C22	MOV	W2, VISI					
0000	000000	NOP						
0001	<visi></visi>	Clock c	out the contents of the VISI register.					
0000	000000	NOP						
Step 5: Clear the	WREN bit.							
0000	200000	MOV	NVMCON, W2					
0000	883B00	VOM	WO, NVMCON					

3.6 Writing Code Memory

For PIC24FJ256GA412/GB412 devices, there are two methods available for writing to code memory: two-word writes using the write latches or 64-word row writes. Figure 3-7 provides a high-level description of the two methods.

Two-word writes program code memory with two instruction words at a time. Two words are loaded into the write latches and the Write Pointer is incremented. Next, the write sequence is initiated, and finally, the WR bit is checked for the sequence to be complete. This process continues for all the data to be programmed.

Table 3-7 provides an example of ICSP programming for a two-word write operation.

FIGURE 3-7: PROGRAM CODE MEMORY FLOW

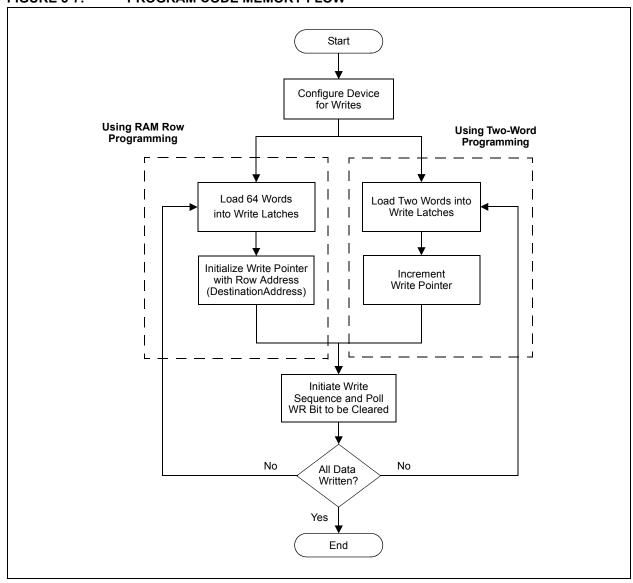


TABLE 3-7: SERIAL INSTRUCTION EXECUTION FOR PROGRAMMING CODE MEMORY: TWO-WORD LATCH WRITES

		1	KIIES
Command (Binary)	Data (Hex)		Description
Step 1: Exit the	e Reset vector.		
0000	000000	NOP	
0000	040200	GOTO	0x200
0000	000000	NOP	
Step 2: Initializ	e the TBLPAG r	egister for w	riting to the latches.
0000	200FAC	MOV	#0xFA, W12
0000	8802AC	MOV	W12, TBLPAG
Step 3: Load V	V0:W2 with the r	next two pac	ked instruction words to program.
0000	2xxxx0	MOV	# <lsw0>, W0</lsw0>
0000	2xxxx1	MOV	# <msb1:msb0>, W1</msb1:msb0>
0000	2xxxx2	MOV	# <lsw1>, W2</lsw1>
Step 4: Set the	Read Pointer (W6) and Wri	te Pointer (W7), and load the (next set of) write latches.
0000	EB0300	CLR	W6
0000	000000	NOP	
0000	EB0380	CLR	W7
0000	000000	NOP	
0000	BB0BB6	TBLWTL	[W6++], [W7]
0000	000000	NOP	
0000	000000	NOP	
0000	BBDBB6		[W6++], $[W7++]$
0000	000000	NOP	
0000	000000	NOP	
0000	BBEBB6		[W6++], $[++W7]$
0000	000000	NOP	
0000	000000	NOP	
0000	BB1BB6		[W6++], [W7++]
0000	000000	NOP	
0000	000000	NOP	
			eter pair to point to the correct address.
0000	2xxxx3	MOV	<pre>#DestinationAddress<15:0>, W3</pre>
0000	2xxxx4	MOV	<pre>#DestinationAddress<23:16>, W4</pre>
0000	883B13	MOV	W3, NVMADR
0000	883B24	MOV	W4, NVMADRU
			am two instruction words.
0000			#0x4001, W10
0000	883B0A	MOV	W10, NVMCON
0000	000000	NOP	
Step 7: Initiate	the write cycle.	T	
0000	200551	MOV	#0x55, W1
0000	883B31	MOV	W1, NVMKEY
0000	200AA1	MOV	#0xAA, W1
0000	883B31	MOV	W1, NVMKEY
0000	A8E761	BSET	NVMCON, #WR
0000	000000	NOP	
0000	000000	NOP	
0000	000000	NOP	

TABLE 3-7: SERIAL INSTRUCTION EXECUTION FOR PROGRAMMING CODE MEMORY: TWO-WORD LATCH WRITES (CONTINUED)

Command (Binary)	Data (Hex)		Description		
Step 8: Wait fo	Step 8: Wait for program operation to complete and make sure the WR bit is clear.				
0000	803B00	MOV	NVMCON, WO		
0000	883C20	MOV	WO, VISI		
0000	000000		,		
0001	<visi></visi>	NOP			
0000	000000	Clock or	ut the contents of the VISI register.		
0000	040200	NOP			
0000	000000	GOTO	0x200		
_	_	NOP			
		Repeat until the WR bit is clear.			
Step 9: Repeat Steps 3-8 until all code memory is programmed.					
Step 10: Clear the WREN bit.					
0000	803B02	MOV	NVMCON, W2		
0000	883B00	MOV	WO, NVMCON		

Row writes program one row (64 instruction words) at a time. First, the Table Pointer is initialized to point to the program latches and data is written into them with Table Writes. Next, the Write Pointer is initialized (NVMADRU and NVMADR register pair) with the row address (DestinationAddress). Finally, the write sequence is initiated and the WR bit is checked for the row programming to be complete. This process is repeated for all data to be programmed. Table 3-8 shows the ICSP programming details for row writes.

To minimize programming time, the data to be programmed is stored in the W0:W5 registers in a packed data format (Figure 3-8). This is the same packed format used by the PE. See Section 6.2.2 "Packed Data Format" for additional information.

FIGURE 3-8: PACKED INSTRUCTION WORD STORAGE IN W0:W5

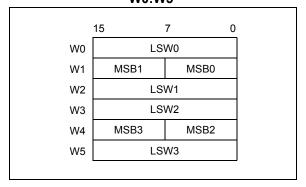


TABLE 3-8: SERIAL INSTRUCTION EXECUTION FOR PROGRAMMING CODE MEMORY: ROW WRITES

NOW WILLES				
Command (Binary)	Data (Hex)	Description		
Step 1: Exit the F	Reset vector.			
0000	000000	NOP		
0000	040200	GOTO	0x200	
0000	000000	NOP		
Step 2: Set the NVMCON register to program 64 instruction words.				
0000	240020	MOV	#0x4002, W0	
0000	883B00	MOV	WO, NVMCON	
Step 3: Initialize	Step 3: Initialize the TBLPAG register for writing to the latches.			
0000	200FAC	MOV	#0xFA, W12	
0000	8802AC	MOV	W12, TBLPAG	
Step 4: Load W0:W5 with the next 4 instruction words to program.				
0000	2xxxx0	MOV	# <lsw0>, W0</lsw0>	
0000	2xxxx1	MOV	# <msb1:msb0>, W1</msb1:msb0>	
0000	2xxxx2	MOV	# <lsw1>, W2</lsw1>	
0000	2xxxx3	MOV	# <lsw2>, W3</lsw2>	
0000	2xxxx4	MOV	# <msb3:msb2>, W4</msb3:msb2>	
0000	2xxxx5	MOV	# <lsw3>, W5</lsw3>	

TABLE 3-8: SERIAL INSTRUCTION EXECUTION FOR PROGRAMMING CODE MEMORY: ROW WRITES (CONTINUED)

	NOW WINITES	
Command (Binary)	Data (Hex)	Description
Step 5: Set the R	ead Pointer (W6)	and load the (next set of) write latches.
0000	EB0300	CLR W6
0000	000000	NOP
0000	EB0380	CLR W7
0000	000000	NOP
0000	BB0BB6	TBLWTL [W6++], [W7]
0000	000000	NOP
0000	000000	NOP
0000	BBDBB6	TBLWTH.B [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BBEBB6	TBLWTH.B [W6++], [++W7]
0000	000000	NOP
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BB0BB6	TBLWTL [W6++], [W7]
0000	000000	NOP
0000	000000	NOP
0000	BBDBB6	TBLWTH.B [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BBEBB6	TBLWTH.B [W6++], [++W7]
0000	000000	NOP
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
Step 6: Repeat S	teps 4 and 5, for	a total of 16 times, to load the write latches with 64 instructions.
Step 7: Set the N	VMADRU/NVMA	DR register pair to point to the correct address.
0000	2xxxx3	MOV #DestinationAddress<15:0>, W3
0000	2xxxx4	MOV #DestinationAddress<23:16>, W4
0000	883B13	MOV W3, NVMADR
0000	883B24	MOV W4, NVMADRU
Step 8: Execute t	he WR bit unlock	sequence and initiate the write cycle.
0000	200550	MOV #0x55, W0
0000	883B30	MOV WO, NVMKEY
0000	200AA0	MOV #0xAA, W0
0000	883B30	MOV WO, NVMKEY
0000	A8E761	BSET NVMCON, #WR
0000	000000	NOP
0000	000000	NOP
0000	000000	NOP
Step 9: Repeat th	is step to poll the	WR bit until it is cleared by hardware.
0000	040200	GOTO 0x200
0000	000000	NOP
0000	803B02	MOV NVMCON, W2
0000	883C22	MOV W2, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
1		

TABLE 3-8: SERIAL INSTRUCTION EXECUTION FOR PROGRAMMING CODE MEMORY: ROW WRITES (CONTINUED)

Command (Binary)	Data (Hex)	Description			
Step 10: Reset th	Step 10: Reset the device's internal Program Counter.				
0000 0000	040200 000000	GOTO 0x200 NOP			
Step 11: Repeat Steps 3 through 9 until all code memory is programmed.					
Step 12: Clear the WREN bit.					
0000 0000	803B02 883B00	MOV NVMCON, W2 MOV W0, NVMCON			

3.7 Writing Configuration Bits

The procedure for writing Configuration bits is similar to the procedure for writing code memory. Table 3-9 shows the ICSP programming details for writing the Configuration bits.

For all Configuration Words, except FBTSEQ, only the lower two bytes of the Word contain configuration data; the upper byte is unused. It is recommended that the upper byte be programmed with 0xFFFF, as indicated in Step 3 (see Table 3-9). FBTSEQ (implemented only in Dual Partition modes) uses all 24 bits of the program memory's width to store the Boot Sequence Number bits, BSEQ[11:0] (FBTSEQ[11:0]), and their one's complement, IBSEQ[11:0] (FBTSEQ[23:12]).

To change the values of the Configuration bits once they have been programmed, the device must be erased, as described in **Section 3.5** "**Erasing Program Memory**", and reprogrammed to the desired value. Note that it is only possible to program a Configuration bit from '1' to '0' to enable code protection; it is not possible to program it from '0' to '1'.

The Flash page on which the Configuration Segment resides is shared with the General Segment. To erase and rewrite the Configuration bits, the entire page must be erased. To avoid losing data held in the General Segment:

- 1. Copy the page to RAM.
- Update the RAM copy with the new Configuration bit values.
- 3. Write back the data to the Flash page.

Alternatively, avoid use of the portion of this Flash page used by the General Segment.

TABLE 3-9: SERIAL INSTRUCTION EXECUTION FOR PROGRAMMING CONFIGURATION WORDS: TWO-WORD LATCH WRITES

IWO-WORD LATCH WRITES				
Command (Binary)	Data (Hex)	Description		
Step 1: Exit the	e Reset vector.			
0000	000000	NOP		
0000	040200	GOTO 0x200		
0000	000000	NOP		
Step 2: Initializ	e the TBLPAG	register for writing to the latches.		
0000	200FAC	MOV #0xFA, W12		
0000	8802AC	MOV W12, TBLPAG		
Step 3: Load V	Step 3: Load W0:W1 with the next two Configuration Words to program.			
0000	2xxxx0	MOV # <lsw0>, W0</lsw0>		
_	_	Upper word is 0xFFFF for all Configuration Words except FBTSEQ.		
0000	2xxxx1	MOV # <msb1:msb0>, W1</msb1:msb0>		
0000	2FFFF2	MOV # <lsw1>, W2</lsw1>		
Step 4: Set the	Read Pointer	(W6) and Write Pointer (W7), and load the (next set of) write latches.		
0000	EB0300	CLR W6		
0000	000000	NOP		
0000	EB0380	CLR W7		
0000	000000	NOP		
0000	BB0BB6	TBLWTL [W6++], [W7]		
0000	000000	NOP		
0000	000000	NOP		
0000	BBDBB6	TBLWTH.B [W6++], [W7++]		
0000	000000	NOP		
0000	000000	NOP		
0000	BBEBB6	TBLWTH.B [W6++], [++W7]		
0000	000000	NOP		
0000	000000	NOP		
0000	BB1BB6	TBLWTL.W [W6++], [W7++]		
0000	000000	NOP		
0000	000000	NOP		

TABLE 3-9: SERIAL INSTRUCTION EXECUTION FOR PROGRAMMING CONFIGURATION WORDS: TWO-WORD LATCH WRITES (CONTINUED)

THE WORLD EATER WILLIAM (CONTINUED)					
Command (Binary)	Data (Hex)		Description		
Step 5: Set the	Step 5: Set the NVMADRU/NVMADR register pair to point to the correct address.				
0000	2xxxx3	MOV	<pre>#DestinationAddress<15:0>, W3</pre>		
0000	2xxxx4	MOV	<pre>#DestinationAddress<23:16>, W4</pre>		
0000	883B13	MOV	W3, NVMADR		
0000	883B24	MOV	W4, NVMADRU		
Step 6: Set the	NVMCON reg	ister to pr	ogram two instruction words.		
0000	24001A	MOV	#0x4001, W10		
0000	883B0A	MOV	W10, NVMCON		
0000	000000	NOP			
Step 7: Initiate	the write cycle).			
0000	200551	MOV	#0x55, W1		
0000	883B31	MOV	W1, NVMKEY		
0000	200AA1	MOV	#0xAA, W1		
0000	883B31	MOV	W1, NVMKEY		
0000	A8E761	BSET	NVMCON, #WR		
0000	000000	NOP			
0000	000000	NOP			
0000	000000	NOP			
Step 8: Wait fo	Step 8: Wait for program operation to complete and make sure the WR bit is clear.				
0000	803B00	MOV	NVMCON, WO		
0000	883C20	MOV	WO, VISI		
0000	000000	NOP			
0001	<visi></visi>		It the contents of the VISI register.		
0000	000000	NOP			
0000	040200	GOTO	0x200		
0000	000000	NOP			
	_		until the WR bit is clear.		
Step 9: Repeat Steps 3-8 until all code memory is programmed.					
Step 10: Clear	Step 10: Clear the WREN bit.				
0000	803B02	MOV	NVMCON, W2		
0000	883B00	VOM	WO, NVMCON		

3.8 Reading Code Memory

Reading from code memory is performed by executing a series of ${\tt TBLRD}$ instructions and clocking out the data using the ${\tt REGOUT}$ command.

Table 3-10 shows the ICSP programming details for reading code memory.

To minimize reading time, the same packed data format that the PE uses is utilized. See **Section 6.2** "**Programming Executive Commands**" for more details on the packed data format.

3.9 Reading Configuration Words

The procedure for reading Configuration Words is identical to the procedure for reading code memory, shown in Table 3-10. Since there are multiple Configuration Words, they are read one at a time.

TABLE 3-10: SERIAL INSTRUCTION EXECUTION FOR READING CODE MEMORY

Command (Binary)	Data (Hex)	Description
Step 1: Exit the Re	eset vector.	
0000	000000	NOP
0000	040200	GOTO 0x200
0000	000000	NOP
Step 2: Initialize th	ne Write Pointer (W	7) to point to the VISI register.
0000	207847	MOV #VISI, W7
0000	000000	NOP
Step 3: Initialize th	ne TBLPAG registe	r and the Read Pointer (W6) for the TBLRD instruction.
0000	200xx0	MOV # <sourceaddress23:16>, W0</sourceaddress23:16>
0000	8802A0	MOV WO, TBLPAG
0000	2xxxx6	MOV # <sourceaddress15:0>, W6</sourceaddress15:0>
-		ents of the next two locations of code memory, through the VISI register, using
the REGOUT comm	nand.	
0000	BA0B96	TBLRDL [W6], [W7]
0000	000000	NOP
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
0000	BADBB6	TBLRDH.B [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BAD3D6	TBLRDH.B [++W6], [W7]
0000	000000	NOP
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
0000	BA0BB6	TBLRDL [W6++], [W7]
0000	000000	NOP
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
Step 5: Reset the	device's internal P	rogram Counter.
0000	040200	GOTO 0x200
0000	000000	NOP
Sten 6: Reneat St	ens 3 through 5 un	til all desired code memory is read (note that "Reset the device's internal

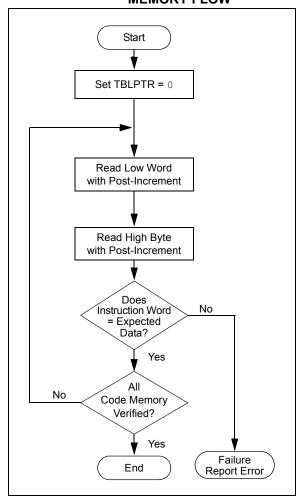
3.10 Verify Code Memory and Configuration Bits

The verify step involves reading back the code memory space and comparing it against the copy held in the programmer's buffer. The Configuration Words are verified with the rest of the code.

The verify process is illustrated in Figure 3-9. The lower word of the instruction is read, and then the lower byte of the upper word is read and compared against the instruction stored in the programmer's buffer. Refer to **Section 3.8 "Reading Code Memory"** for implementation details of reading code memory.

Note: Because the Configuration bytes include the device code protection bit, code memory should be verified immediately after writing if the code protection is to be enabled. This is because the device will not be readable or verifiable if a device Reset occurs after the code-protect bit has been cleared.

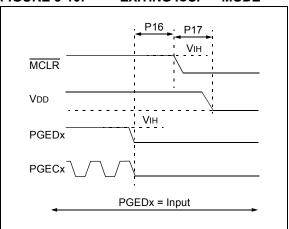
FIGURE 3-9: VERIFY CODE MEMORY FLOW



3.11 Exiting ICSP Mode

Exiting Program/Verify mode is done by removing VIH from MCLR, as illustrated in Figure 3-10. The only requirement for exit is that an interval, P16, should elapse between the last clock, and program signals on PGECx and PGEDx, before removing VIH.

FIGURE 3-10: EXITING ICSP™ MODE



4.0 DEVICE PROGRAMMING – ENHANCED ICSP

This section discusses programming the device through Enhanced ICSP and the Programming Executive (PE). The PE resides in executive memory (separate from code memory) and is executed when Enhanced ICSP Programming mode is entered. The PE provides the mechanism for the programmer (host device) to program and verify the PIC24FJ256GA412/GB412 family devices, using a simple command set and communication protocol. There are several basic functions provided by the PE:

- · Read Memory
- · Erase Memory
- · Program Memory
- · Blank Check

The PE performs the low-level tasks required for erasing, programming and verifying a device. This allows the programmer to program the device by issuing the appropriate commands and data. A detailed description for each command is provided in Section 6.2 "Programming Executive Commands".

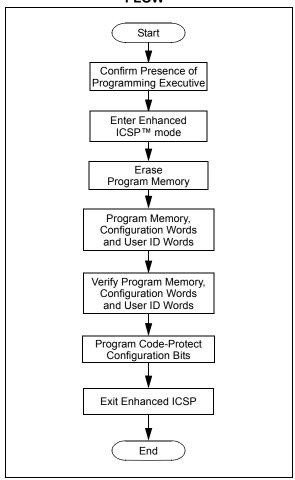
Note

The PE uses the device's data RAM for variable storage and program execution. After running the PE, no assumptions should be made about the contents of data RAM.

4.1 Overview of the Programming Process

Figure 4-1 shows the high-level overview of the programming process. First, it must be determined if the PE is present in executive memory, and then, Enhanced ICSP mode is entered. The program memory is then erased, and the program memory and Configuration Words are programmed and verified. Last, the code-protect Configuration bits are programmed (if required) and Enhanced ICSP mode is exited.

FIGURE 4-1: HIGH-LEVEL ENHANCED ICSP™ PROGRAMMING FLOW



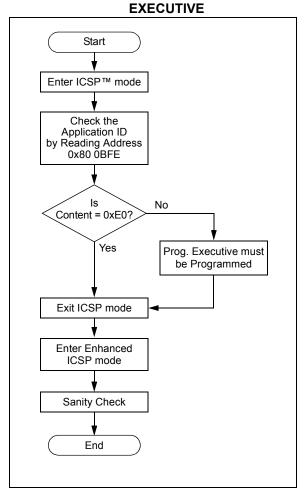
4.2 Confirming the Presence of the Programming Executive

Before programming, the programmer must confirm that the PE is stored in executive memory. The procedure for this task is illustrated in Figure 4-2.

First, ICSP mode is entered. Then, the unique Application ID Word, stored in executive memory, is read. If the Application ID has the value, 0xE0, the Programming Executive is resident in memory and the device can be programmed. However, if the Application ID Word is not present, the PE must be programmed to executive code memory using the method described in Section 5.0 "Programming the Programming Executive to Memory".

Section 3.0 "Device Programming – ICSP" describes the ICSP programming method. Section 4.3 "Reading the Application ID Word" describes the procedure for reading the Application ID Word in ICSP mode.

FIGURE 4-2: CONFIRMING PRESENCE OF PROGRAMMING



4.3 Reading the Application ID Word

The Application ID Word is stored at address, 0x80 0FF0, in executive code memory. To read this memory location, you must use the SIX control code to move this program memory location to the VISI register. Then, the REGOUT control code must be used to clock the contents of the VISI register out of the device. The corresponding control and instruction codes that must be serially transmitted to the device to perform this operation are shown in Table 4-1.

If the Application ID has the value, 0x0E, the Programming Executive is resident in memory and the device can be programmed using the mechanism described in this section. However, if the Application ID has any other value, the PE is not resident in memory; it must be loaded to memory before the device can be programmed. The procedure for loading the PE to memory is described in Section 5.0 "Programming the Programming Executive to Memory".

TABLE 4-1: SERIAL INSTRUCTION EXECUTION FOR READING THE APPLICATION ID WORD

IADLE 4-1.	SERIAL INST	KUCTION	EXECUTION FOR READING THE APPLICATION ID WORD	
Command (Binary)	Data (Hex)		Description	
Step 1: Exit th	e Reset vector.			
0000	000000	NOP		
0000	040200	GOTO	0x200	
0000	000000	NOP		
Step 2: Initializ	ze the TBLPAG re	gister and th	ne Read Pointer (W0) for the TBLRD instruction.	
0000	200800	MOV	#0x80, W0	
0000	8802A0	MOV	WO, TBLPAG	
0000	20FF00	MOV	#Oxff0, WO	
0000	207841	MOV	#VISI, W1	
0000	000000	NOP		
0000	BA0890	TBLRDL	[WO], [W1]	
0000	000000	NOP		
0000	000000	NOP		
0000	000000	NOP		
Step 3: Output	Step 3: Output the VISI register using the REGOUT command.			
0001	<visi></visi>	Clock out t	he contents of the VISI register.	

4.4 Entering Enhanced ICSP Mode

As illustrated in Figure 4-3, entering Enhanced ICSP Program/Verify mode requires three steps:

- The MCLR pin is briefly driven high and then low.
- 2. A 32-bit key sequence is clocked into PGEDx.
- 3. MCLR is then driven high within a specified period of time and held.

The programming voltage applied to MCLR is VIH, which is essentially VDD in PIC24FJ256GA412/GB412 family devices. There is no minimum time requirement for holding at VIH. After VIH is removed, an interval of at least P18 must elapse before presenting the key sequence on PGEDx.

The key sequence is a specific 32-bit pattern, '0100 1101 0100 0011 0100 1000 0101 0000' (more easily remembered as 0x4D43 4850 in hexadecimal format). The device will enter Program/Verify mode only if the key sequence is valid. The Most Significant bit (MSb) of the most significant nibble must be shifted in first.

Once the key sequence is complete, VIH must be applied to MCLR and held at that level for as long as Program/Verify mode is to be maintained. An interval time of at least P19, P7 and P1 * 5 must elapse before presenting data on PGEDx. During the P7 interval, the programmer's PGEDx and PGECx lines must be tri-stated.

On successful entry, the program memory can be accessed and programmed in serial fashion. While in the Program/Verify mode, all unused I/Os are placed in the high-impedance state.

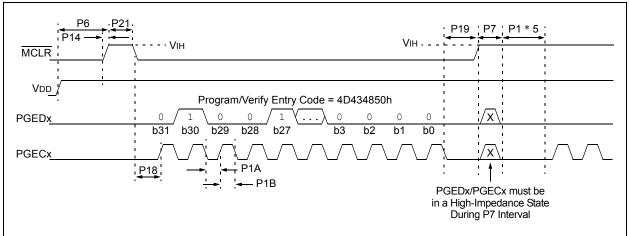
4.5 Blank Check

The term, "Blank Check", implies verifying that the device has been successfully erased and has no programmed memory locations. A blank or erased memory location is always read as '1'.

The Device ID registers (0xFF 0000:0xFF 0002) can be ignored by the Blank Check, since this region stores device information that cannot be erased. Additionally, all unimplemented memory space should be ignored by the Blank Check.

The QBLANK command is used for the Blank Check. It determines if the code memory is erased by testing these memory regions. A 'BLANK' or 'NOT BLANK' response is returned. If it is determined that the device is not blank, it must be erased before attempting to program the chip.

FIGURE 4-3: ENTERING ENHANCED ICSP™ MODE



4.6 **Code Memory Programming**

4.6.1 PROGRAMMING METHODOLOGY

There are two commands that can be used for programming code memory when utilizing the PE. The PROG2W command programs and verifies two 24-bit instruction words into the program memory, starting at the address specified. The second and faster command, PROGP, allows up to 64 instruction words (each 24 bits) to be programmed and verified into program memory, starting at the address specified. See Section 6.0 "The Programming Executive" for a full description of each of these commands.

FIGURE 4-4: **FLOWCHART FOR DOUBLE-WORD PROGRAMMING**

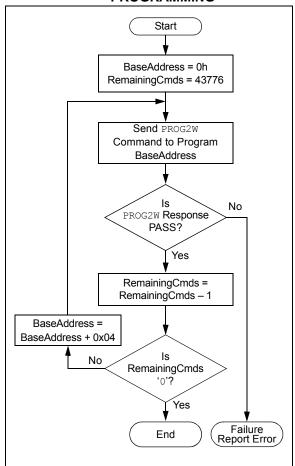
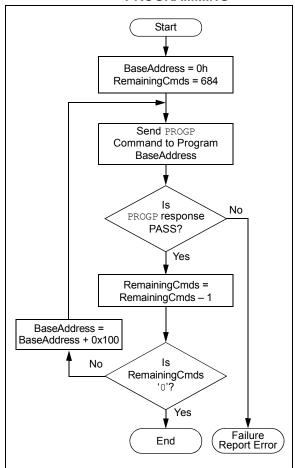


Figure 4-4 and Figure 4-5 show the programming methodology for the PROG2W and PROGP commands. In both instances, 87552 instruction words of the device are programmed.

Note:

If a bootloader needs to be programmed, its code must not be programmed into the first page of code memory. For example, if a bootloader located at address, 0x200, attempts to erase the first page, it would inadvertently erase itself. Instead, program the bootloader into the second page (e.g., 0x400).

FIGURE 4-5: **FLOWCHART FOR MULTIPLE WORD PROGRAMMING**

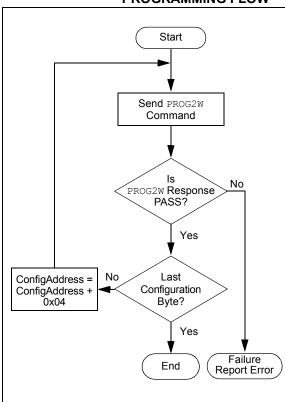


4.7 Configuration Bit Programming

Configuration bits are programmed one at a time using the PROG2W command. This command specifies the configuration data and address. When Configuration bits are programmed, any unimplemented bits must be programmed with a '1'.

Multiple PROG2W commands are required to program all Configuration bits. A flowchart for Configuration bit programming is shown in Figure 4-6.

FIGURE 4-6: CONFIGURATION BIT PROGRAMMING FLOW



4.8 Programming Verification

After code memory is programmed, the contents of memory can be verified to ensure that programming was successful. Verification requires code memory to be read back and compared against the copy held in the programmer's buffer.

The READP command can be used to read back all the programmed code memory and Configuration Words.

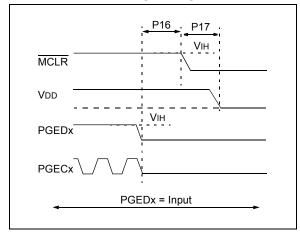
Alternatively, you can have the programmer perform the verification after the entire device is programmed using a checksum computation.

See **Section 9.0 "Checksum Computation"** for more information on calculating the checksum.

4.9 Exiting Enhanced ICSP Mode

Exiting Program/Verify mode is done by removing VIH from MCLR, as illustrated in Figure 4-7. The only requirement for exit is that an interval, P16, should elapse between the last clock, and program signals on PGECx and PGEDx before removing VIH.

FIGURE 4-7: EXITING ENHANCED ICSP™ MODE



5.0 PROGRAMMING THE PROGRAMMING EXECUTIVE TO MEMORY

Note:

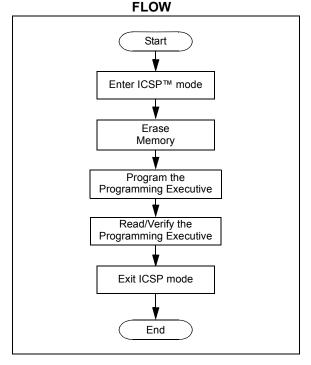
The Programming Executive (PE) can be obtained from each device page on the Microchip website: www.microchip.com.

5.1 Overview

If it is determined that the PE is not present in executive memory (as described in **Section 4.2 "Confirming the Presence of the Programming Executive"**), the PE must be programmed to executive memory.

Figure 5-1 shows the high-level process of programming the PE into executive memory. First, ICSP mode must be entered, and executive memory and user memory are erased; then, the PE is programmed and verified. Finally, ICSP mode is exited.

FIGURE 5-1: HIGH-LEVEL PROGRAMMING EXECUTIVE PROGRAM



5.2 Erasing Executive Memory

Executive memory is erased by a series of Page Erase operations, as shown in Figure 5-2. This consists of several cycles of setting NVMCON to 0x400E, executing the programming cycle and repeating these steps for each page of executive memory.

Table 5-1 illustrates the ICSP programming process for Chip Erasing memory.

Note:

The PE must always be erased before it is programmed, as shown in Figure 5-1.

FIGURE 5-2: PAGE ERASE FLOW

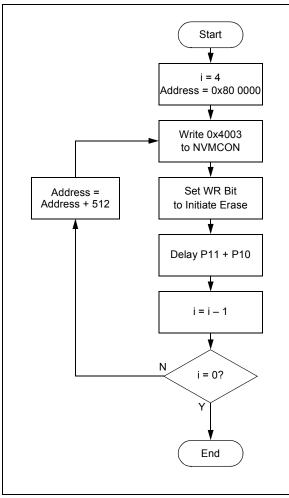


TABLE 5-1: SERIAL INSTRUCTION EXECUTION FOR ERASING EXECUTIVE MEMORY

IABLE 3-1.	OLIVIAL ING	11(00110)	N EXECUTION FOR ERASING EXECUTIVE MEMORT
Command (Binary)	Data (Hex)		Description
Step 1: Exit th	e Reset vector.		
0000	000000	NOP	
0000	040200	GOTO	0x200
0000	000000	NOP	
0000	000000	NOP	
Step 2: Set the	e NVMCON regis	ter to erase	a page.
0000	240030	MOV	#0x4003, W0
0000	883B00	MOV	WO, NVMCON
Step 3: Load t	he address of the	page to be	erased into the NVMADR register pair.
0000	200004	MOV	#0000, W4
0000	883B14	MOV	W4, NVMADR
0000	200800	MOV	#0080, W0
0000	883B20	MOV	WO, NVMADRU
Step 4: Set the	e WR bit.		
0000	200550	MOV	#0x55, W0
0000	883B30	MOV	WO, NVMKEY
0000	200AA0	MOV	#0xAA, W0
0000	883B30	MOV	WO, NVMKEY
0000	A8E761	BSET	NVMCON, #WR
0000	000000	NOP	
0000	000000	NOP	
0000	000000	NOP	
Step 5: Repea	it this step to poll	the WR bit	until it is cleared by hardware.
0000	040200	GOTO	0x200
0000	000000	NOP	
0000	803B02	MOV	NVMCON, W2
0000	883C22	MOV	W2, VISI
0000	000000	NOP	at the contents of the VICI register
0001 0000	<visi></visi>	NOP	t the contents of the VISI register.
	nent W4 by 1024	-	
•	1	·	#0400 tr2
0000 0000	204003 418204	MOV ADD	#0x400, W3 W3, W4, W4
0000	883B24	MOV	W4, NVMADRU
		-	st memory has been erased.
Step 8: Clear t	•	iie eiiliie le	Stillethory has been eraseu.
•		MOT?	NUMCONI DIO
0000 0000	803B02 883B00	MOV MOV	NVMCON, W2 W0, NVMCON
0000	003500	INO A	WO, INVITICOIN

5.3 Program the Programming Executive

Storing the PE to executive memory is similar to normal programming of code memory. The executive memory must first be erased, and then programmed, using either two-word writes (two instruction words) or row writes (64 instruction words). The control flow for both methods is identical to that for programming code memory, as shown in Figure 3-7.

Table 5-2 and Table 5-3 illustrate the ICSP programming processes for PE memory. To minimize programming time, the same packed data format that the PE uses is utilized. See **Section 6.2 "Programming Executive Commands"** for more details on the packed data format.

TABLE 5-2: PROGRAMMING THE PROGRAMMING EXECUTIVE (TWO-WORD LATCH WRITES)

(TVVO-VVORD LATCH VVRITES)						
Command (Binary)	Data (Hex)		Description			
Step 1: Exit the	e Reset vector.					
0000	000000	NOP				
0000	040200	GOTO	0x200			
0000	000000	NOP				
Step 2: Initializ	e the TBLPAG reg	ister for writing	g to the latches.			
0000	200FAC	MOV	#0xFA, W12			
0000	8802AC	MOV	W12, TBLPAG			
Step 3: Load V	W0:W2 with the nex	t two packed	instruction words to program.			
0000	2xxxx0	MOV	# <lsw0>, W0</lsw0>			
0000	2xxxx1	MOV	# <msb1:msb0>, W1</msb1:msb0>			
0000	2xxxx2	MOV	# <lsw1>, W2</lsw1>			
Step 4: Set the	e Read Pointer (W6	s) and the Writ	te Pointer (W7), and load the write latches.			
0000	EB0300	CLR	W6			
0000	000000	NOP				
0000	EB0380	CLR	w7			
0000	000000	NOP				
0000	BB0BB6	TBLWTL	[W6++], [W7]			
0000	000000	NOP	2, 2			
0000	000000	NOP				
0000	BBDBB6	TBLWTH.B	[W6++], [W7++]			
0000	000000	NOP				
0000	000000	NOP				
0000	BBEBB6	TBLWTH.B	[W6++], [++W7]			
0000	000000	NOP				
0000	000000	NOP				
0000	BB1BB6	TBLWTL.W	[W6++], [W7++]			
0000	000000	NOP				
0000	000000	NOP				
Step 5: Set the	e NVMADRU/NVM	ADR register p	pair to point to the correct row.			
0000	2xxxx3	MOV	#DestinationAddress<15:0>, W3			
0000	2xxxx4	MOV	#DestinationAddress<23:16>, W4			
0000	883B13	MOV	W3, NVMADR			
0000	883B24	MOV	W4, NVMADRU			
Step 6: Set the	e NVMCON registe	r to program t	wo instruction words.			
0000	24001A	MOV	#0x4001, W10			
0000	000000	NOP	·			
0000	883B0A	MOV	W10, NVMCON			
0000	000000	NOP	·			
0000	000000	NOP				
		1				

TABLE 5-2: PROGRAMMING THE PROGRAMMING EXECUTIVE (TWO-WORD LATCH WRITES) (CONTINUED)

	(TWO-WORD EATON WINDED)				
Command (Binary)	Data (Hex)		Description		
Step 7: Initiate	the write cycle.				
0000	200551	MOV	#0x55, W1		
0000	883B31	MOV	W1, NVMKEY		
0000	200AA1	MOV	#0xAA, W1		
0000	883B31	MOV	W1, NVMKEY		
0000	A8E761	BSET	NVMCON, #WR		
0000	000000	NOP			
0000	000000	NOP			
0000	000000	NOP			
0000	000000	NOP			
0000	000000	NOP			
Step 8: Wait fo	r program operation	n to complet	te and make sure the WR bit is clear.		
0000	000000	NOP			
0000	803B00	MOV	NVMCON, WO		
0000	000000	NOP			
0000	883C20	MOV	WO, VISI		
0000	000000	NOP			
0001	<visi></visi>	Clock ou	t the contents of the VISI register.		
0000	000000	NOP	•		
0000	040200	GOTO	0x200		
0000	000000	NOP			
_	_	Repeat u	ıntil the WR bit is clear.		
Step 9: Repea	t Steps 3-8 until all	code memo	ry is programmed.		
Step 10: Clear	the WREN bit.				
0000	803B02	MOV	NVMCON, W2		
0000	883B00	MOV	WO, NVMCON		

TABLE 5-3: PROGRAMMING THE PROGRAMMING EXECUTIVE (ROW WRITES)

IADLE 5-3:	PROGRAMMMING THE PROGRAMMMING EXECUTIVE (ROW WRITES)				
Command (Binary)	Data (Hex)	Description			
Step 1: Exit the	e Reset vector.				
0000	000000	NOP			
0000	040200	GOTO	0x200		
0000	000000	NOP			
Step 2: Set the	NVMCON regist	er to progran	n 64 instruction words.		
0000	240020	MOV	#0x4002, W0		
0000	883B00	MOV	WO, NVMCON		
Step 3: Initializ	e the TBLPAG re	gister for writ	ting to the latches.		
0000	200FAC	MOV	#0xFA, W12		
0000	8802AC	MOV	W12, TBLPAG		
Step 4: Load V	V0:W5 with the no	ext 4 instructi	on words to program.		
0000	2xxxx0	MOV	# <lswo>, WO</lswo>		
0000	2xxxx1	MOV	# <msb1:msb0>, W1</msb1:msb0>		
0000	2xxxx2	MOV	# <lsw1>, W2</lsw1>		
0000	2xxxx3	MOV	# <lsw2>, W3</lsw2>		
0000	2xxxx4	MOV	# <msb3:msb2>, W4</msb3:msb2>		
0000	2xxxx5	MOV	# <lsw3>, W5</lsw3>		
Step 5: Set the	Read Pointer (V	/6) and load	the (next set of) write latches.		
0000	EB0300	CLR	W6		
0000	000000	NOP			
0000	EB0380	CLR	W7		
0000	000000	NOP			
0000	BBDBB6	TBLWTL	[W6++], [W7]		
0000	000000	NOP			
0000	000000	NOP			
0000	BBEBB6	TBLWTH.B	[W6++], [++W7]		
0000	000000	NOP			
0000	000000	NOP			
0000	BB1BB6	TBLWTL	[W6++], [W7++]		
0000	000000	NOP			
0000	000000	NOP	[27.6.4.] [27.7.]		
0000	BB0BB6	TBLWTL	[W6++], [W7]		
0000	000000	NOP			
0000	000000 BBDBB6	NOP	[W6++] [W7++]		
0000	000000		[W6++], [W7++]		
0000	000000	NOP NOP			
0000	BBEBB6	TBLWTH.B	[W6++], [++W7]		
0000	000000	NOP	[u<] [[, , m,]		
0000	000000	NOP			
0000	BB1BB6	TBLWTL	[W6++], [W7++]		
0000	000000	NOP	[] []		
0000	000000	NOP			
			6 times, to load the write latches with 64 instructions.		
			er pair to point to the correct address.		
0000	2xxxx3	MOV	#DestinationAddress<15:0>, W3		
0000	2xxxx4	MOV	#DestinationAddress<23:16>, W4		
0000	883B13	MOV	W3, NVMADR		
0000	883B24	MOV	W4, NVMADRU		
3000		1	,		

TABLE 5-3: PROGRAMMING THE PROGRAMMING EXECUTIVE (ROW WRITES) (CONTINUED)

IABLE 3-3.	PROGRAMMING THE PROGRAMMING EXECUTIVE (ROW WRITES) (CONTINUED)			
Command (Binary)	Data (Hex)		Description	
Step 8: Execu	te the WR bit un	lock seque	nce and initiate the write cycle.	
0000	200551	MOV	#0x55, W1	
0000	883B31	MOV	W1, NVMKEY	
0000	200AA1	MOV	#0xAA, W1	
0000	883B31	MOV	W1, NVMKEY	
0000	A8E761	BSET	NVMCON, #WR	
0000	000000	NOP		
0000	000000	NOP		
0000	000000	NOP		
0000	000000	NOP		
0000	000000	NOP		
Step 9: Repea	t this step to pol	I the WR b	it until it is cleared by hardware.	
0000	040200	GOTO	0x200	
0000	000000	NOP		
0000	803B00	MOV	NVMCON, WO	
0000	883C20	MOV	WO, VISI	
0000	000000	NOP		
0001	<visi></visi>	Clock ou	t the contents of the VISI register.	
0000	000000	NOP		
Step 10: Rese	t the device's int	ternal Prog	ram Counter.	
0000	040200	GOTO	0x200	
0000	000000	NOP		
Step 11: Repe	at Steps 3 throu	gh 9 until a	Ill code memory is programmed.	
Step 12: Clear	the WREN bit.			
0000	803B02	MOV	NVMCON, W2	
0000	883B00	MOV	WO, NVMCON	

5.4 Reading Executive Memory

Reading from executive memory is performed by executing a series of ${\tt TBLRD}$ instructions and clocking out the data using the ${\tt REGOUT}$ command.

Table 5-4 shows the ICSP programming details for reading executive memory.

To minimize reading time, the same packed data format that the PE uses is utilized. See **Section 6.2 "Programming Executive Commands"** for more details on the packed data format.

TABLE 5-4: SERIAL EXECUTION FOR READING EXECUTIVE MEMORY

Command (Binary)	Data (Hex)	Description		
Step 1: Exit the Re	set vector.			
0000	000000	NOP		
0000	040200	GOTO	0x200	
0000	000000	NOP		
Step 2: Initialize the	e TBLPAG register a	nd the Read	Pointer (W6) for the TBLRD instruction.	
0000	200xx0	MOV	# <sourceaddress23:16>, W0</sourceaddress23:16>	
0000	8802A0	MOV	WO, TBLPAG	
0000	2xxxx6	MOV	# <sourceaddress15:0>, W6</sourceaddress15:0>	
Step 3: Initialize the	Write Pointer (W7)	and store the	e next four locations of code memory in W0:W5.	
0000	EB0380	CLR	W7	
0000	000000	NOP		
0000	BA1B96	TBLRDL	[W6], [W7++]	
0000	000000	NOP		
0000	000000	NOP		
0000	BADBB6	TBLRDH.B	[W6++], [W7++]	
0000	000000	NOP		
0000	000000	NOP		
0000	BADBD6	TBLRDH.B	[++W6], [W7++]	
0000	000000	NOP		
0000	000000	NOP		
0000	BA1BB6	TBLRDL	[W6++], [W7++]	
0000	000000	NOP		
0000	000000	NOP		
0000	BA1B96	TBLRDL	[W6], [W7++]	
0000	000000	NOP		
0000	000000	NOP		
0000	BADBB6	TBLRDH.B	[W6++], [W7++]	
0000	000000	NOP		
0000	000000	NOP		
0000	BADBD6	TBLRDH.B	[++W6], [W7++]	
0000	000000	NOP		
0000	000000	NOP		
0000	BA0BB6	TBLRDL	[W6++], [W7]	
0000	000000	NOP		
0000	000000	NOP		

TABLE 5-4: SERIAL EXECUTION FOR READING EXECUTIVE MEMORY (CONTINUED)

Command (Binary)	Data (Hex)	Description
Step 4: Output W0	:W5 using the VIS	register and the REGOUT command.
0000	883C20	MOV WO, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
0000	883C21	MOV W1, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
0000	883C22	MOV W2, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
0000	883C23	MOV W3, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
0000	883C24	MOV W4, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
0000	883C25	MOV W5, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out the contents of the VISI register.
0000	000000	NOP
Step 5: Reset the	device's internal Pr	ogram Counter.
0000	000000	NOP
0000	040200	GOTO 0x200
0000	000000	NOP

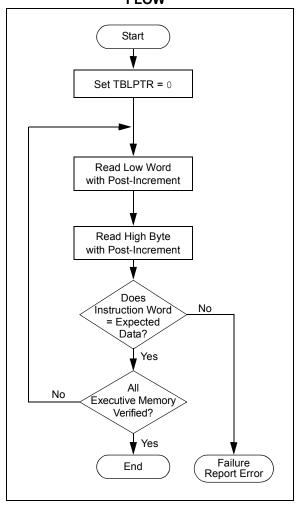
Step 6: Repeat Steps 3 through 5 until all desired code memory is read (note that "Reset the device's internal Program Counter" will be Step 5).

5.5 Verify Programming Executive

The verify step involves reading back the executive memory space and comparing it against the copy held in the programmer's buffer.

The verify process is illustrated in Figure 5-3. The lower word of the instruction is read, and then the lower byte of the upper word is read and compared against the instruction stored in the programmer's buffer. Refer to Section 5.4 "Reading Executive Memory" for implementation details of reading executive memory.

FIGURE 5-3: VERIFY PROGRAMMING EXECUTIVE MEMORY FLOW



6.0 THE PROGRAMMING EXECUTIVE

6.1 Programming Executive Communication

The programmer and PE have a master-slave relationship, where the programmer is the master programming device and the PE is the slave.

All communication is initiated by the programmer in the form of a command. Only one command at a time can be sent to the PE. In turn, the PE only sends one response to the programmer after receiving and processing a command. The PE command set is described in **Section 6.2 "Programming Executive Commands"**. The response set is described in **Section 6.3 "Programming Executive Responses"**.

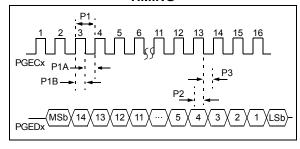
6.1.1 COMMUNICATION INTERFACE AND PROTOCOL

The ICSP/Enhanced ICSP interface is a 2-wire SPI, implemented using the PGECx and PGEDx pins. The PGECx pin is used as a clock input pin and the clock source must be provided by the programmer. The PGEDx pin is used for sending command data to and receiving response data from the PE.

Note: For Enhanced ICSP, all serial data is transmitted on the falling edge of PGECx and latched on the rising edge of PGECx. All data transmissions are sent to the MSb first using 16-bit mode (see Figure 6-1).

Since a 2-wire SPI is used, and data transmissions are bidirectional, a simple protocol is used to control the direction of PGEDx. When the programmer completes a command transmission, it releases the PGEDx line and allows the PE to drive this line high. The PE keeps the PGEDx line high to indicate that it is processing the command.

FIGURE 6-1: PROGRAMMING EXECUTIVE SERIAL TIMING

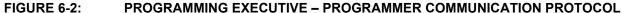


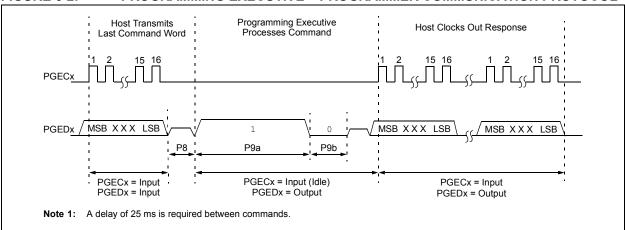
After the PE has processed the command, it brings PGEDx low (P9B) to indicate to the programmer that the response is available to be clocked out. The programmer can begin to clock out the response after a maximum wait (P9B) and it must provide the necessary amount of clock pulses to receive the entire response from the PE.

After the entire response is clocked out, the programmer should terminate the clock on PGECx until it is time to send another command to the PE. This protocol is illustrated in Figure 6-2.

6.1.2 SPI RATE

In Enhanced ICSP mode, PIC24FJ256GA412/GB412 family devices operate from the Fast Internal RC (FRC) oscillator, which has a nominal frequency of 8 MHz. This oscillator frequency yields an effective system clock frequency of 4 MHz. To ensure that the programmer does not clock too fast, it is recommended that a 2 MHz clock be provided by the programmer.





6.1.3 TIME-OUTS

The PE uses no Watchdog Timer or time-out for transmitting responses to the programmer. If the programmer does not follow the flow control mechanism, using PGECx as described in **Section 6.1.1 "Communication Interface and Protocol"**, it is possible that the PE will behave unexpectedly while trying to send a response to the programmer. Since the PE has no time-out, it is imperative that the programmer correctly follow the described communication protocol.

As a safety measure, the programmer should use the command time-outs identified in Table 6-1. If the command time-out expires, the programmer should reset the PE and start programming the device again.

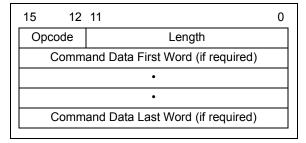
6.2 Programming Executive Commands

The PE command set is shown in Table 6-1. This table contains the opcode, mnemonic, length, time-out and description for each command. Functional details on each command are provided in the command descriptions (Section 6.2.4 "Command Descriptions").

6.2.1 COMMAND FORMAT

All PE commands have a general format, consisting of a 16-bit header and any required data for the command (see Figure 6-3). The 16-bit header consists of a 4-bit opcode field, which is used to identify the command, followed by a 12-bit command length field.

FIGURE 6-3: COMMAND FORMAT



The command opcode must match one of those in the command set. Any command that is received which does not match the list in Table 6-1 will return a "NACK" response (see **Section 6.3.1.1 "Opcode Field"**).

The command length is represented in 16-bit words since the SPI operates in 16-bit mode. The PE uses the command length field to determine the number of words to read from the SPI port. If the value of this field is incorrect, the command will not be properly received by the PE.

TABLE 6-1: PROGRAMMING EXECUTIVE COMMAND SET

Opcode	Mnemonic	Length (16-bit words)	Time-out	Description
0x0	SCHECK	1	1 ms	Sanity check.
0x1	READC	3	1 ms	Read an 8-bit word from the specified Configuration register or Device ID register.
0x2	READP	4	1 ms/row	Read 'N' 24-bit instruction words of primary Flash memory, starting from the specified address.
0x3	PROG2W	6	5 ms	Program a double instruction word of code memory at the specified address and verify.
0x4	Reserved	N/A	N/A	This command is reserved; it will return a NACK.
0x5	PROGP	99	5 ms	Program 64 words of program memory at the specified starting address, then verify.
0x6	Reserved	N/A	N/A	This command is reserved; it will return a NACK.
0x7	ERASEB	1	125 ms	Chip Erase the device.
0x8	Reserved	N/A	N/A	This command is reserved; it will return a NACK.
0x9	ERASEP	3	25 ms	Command to erase a page.
0xA	Reserved	N/A	N/A	This command is reserved; it will return a NACK.
0xB	QVER	1	1 ms	Query the PE software version.
0xC	CRCP	5	1s	Performs a CRC-16 on the specified range of memory.
0xD	Reserved	N/A	N/A	This command is reserved; it will return a NACK.
0xE	QBLANK	5	700 ms	Query to check whether the code memory is blank.

6.2.2 PACKED DATA FORMAT

When 24-bit instruction words are transferred across the 16-bit SPI interface, they are packed to conserve space using the format illustrated in Figure 6-4. This format minimizes traffic over the SPI and provides the PE with data that is properly aligned for performing Table Write operations.

FIGURE 6-4: PACKED INSTRUCTION WORD FORMAT

15		8	7	0
		LS	W1	
	MSB2		MSB1	
		LS'	W2	

LSWx: Least Significant 16 bits of instruction word MSBx: Most Significant Byte of instruction word

Note: When the number of instruction words transferred is odd, MSB2 is zero and LSW2 cannot be transmitted.

6.2.3 PROGRAMMING EXECUTIVE ERROR HANDLING

The PE will "NACK" all unsupported commands. Additionally, due to the memory constraints of the PE, no checking is performed on the data contained in the programmer command. It is the responsibility of the programmer to command the PE with valid command arguments or the programming operation may fail. Additional information on error handling is provided in Section 6.3.1.3 "QE_Code Field".

6.2.4 COMMAND DESCRIPTIONS

All commands supported by the PE are described in Section 6.2.4.1 "SCHECK Command" through Section 6.2.4.10 "QBLANK Command".

6.2.4.1 SCHECK Command

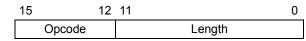


Table 6-2 shows the description for the ${\tt SCHECK}$ command.

TABLE 6-2: COMMAND DESCRIPTION

Field	Description
Opcode	0x0
Length	0x1

The SCHECK command instructs the PE to do nothing but generate a response. This command is used as a "Sanity Check" to verify that the PE is operational.

Expected Response (2 words):

0x1000 0x0002

Note:	This i	instructio	n is	not	required	for
	prograi	mming,	but	is	provided	for
	develo	pment pu	rpose	s onl	y.	

6.2.4.2 READC Command

15 12 11 8 7 0

Opcode Length

N Addr_MSB

Addr_LS

Table 6-3 shows the description for the READC command.

TABLE 6-3: COMMAND DESCRIPTION

Field	Description
Opcode	0x1
Length	0x3
N	Number of 8-bit Configuration registers or Device ID registers to read (maximum of 256)
Addr_MSB	MSB of 24-bit source address.
Addr_LS	Least Significant 16 bits of 24-bit source address

The READC command instructs the PE to read N Configuration registers or Device ID registers, starting from the 24-bit address specified by Addr_MSB and Addr_LS. This command can only be used to read 8-bit or 16-bit data.

When this command is used to read Configuration registers, the upper byte in every data word returned by the PE is 0x00 and the lower byte contains the Configuration register value.

Expected Response (4 + 3 * (N - 1)/2 words) for N odd):

0x1100

2 + N

Configuration register or Device ID Register 1

Configuration register or Device ID Register N

Note:	Reading unimplemented memory will
	cause the PE to reset. To prevent this from
	occurring, ensure that only memory loca-
	tions present on a particular device are
	accessed.

6.2.4.3 READP Command

 15
 12
 11
 8
 7
 0

 Opcode
 Length

 N

 Reserved
 Addr_MSB

 Addr_LS

Table 6-4 shows the description for the READP command.

TABLE 6-4: COMMAND DESCRIPTION

Field	Description
Opcode	0x2
Length	0x4
N	Number of 24-bit instructions to read (maximum of 32768)
Reserved	0x0
Addr_MSB	MSB of 24-bit source address
Addr_LS	Least Significant 16 bits of 24-bit source address

The READP command instructs the PE to read N 24-bit words of code memory, starting from the 24-bit address specified by Addr_MSB and Addr_LS. This command can only be used to read 24-bit data. All data returned in response to this command uses the packed data format described in Section 6.2.2 "Packed Data Format".

Expected Response (2 + 3 * N/2 words for N even):

0x1200

2 + 3 * N/2

Least Significant Program Memory Word 1

...

Least Significant Data Word N

Expected Response (4 + 3 * (N - 1)/2 words) for N odd):

0x1200

4 + 3 * (N - 1)/2

Least Significant Program Memory Word 1

• • •

MSB of Program Memory Word N (zero-padded)

Note: Reading unimplemented memory will cause the PE to reset. To prevent this from occurring, ensure that only memory locations present on a particular device are accessed.

6.2.4.4 PROG2W Command

15	12	11	8	7		0
Opcode				Len	igth	
Rese		rved			Addr_MSB	
			Addr_	LS		
			DataL	_LS		
DataH_MSB			,		DataL_MSB	
	DataH_LS					

Table 6-5 shows the description for the PROG2W command.

TABLE 6-5: COMMAND DESCRIPTION

., ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	
Field	Description
Opcode	0x3
Length	0x6
DataL_MSB	MSB of 24-bit data for low instruction word
DataH_MSB	MSB of 24-bit data for high instruction word
Addr_MSB	MSB of 24-bit destination address
Addr_LS	Least Significant 16 bits of 24-bit destination address
DataL_LS	Least Significant 16 bits of 24-bit data for low instruction word
DataH_LS	Least Significant 16 bits of 24-bit data for high instruction word

The PROG2W command instructs the PE to program two instruction words of code memory (6 bytes) to the specified memory address.

After the words have been programmed to code memory, the PE verifies the programmed data against the data in the command.

Expected Response (2 words):

0x1300 0x0002 6.2.4.5 PROGP Command

15 12 11 8 7 0

Opcode Length

Reserved Addr_MSB

Addr_LS

D_1

D_2

...

D_N

Table 6-6 shows the description for the ${\tt PROGP}$ command.

TABLE 6-6: COMMAND DESCRIPTION

Field	Description	
Opcode	0x5	
Length	0x63	
Reserved	0x0	
Addr_MSB	MSB of 24-bit destination address	
Addr_LS	Least Significant 16 bits of 24-bit destination address	
D_1	16-bit Data Word 1	
D_2	16-bit Data Word 2	
	16-bit Data Word 3 through 95	
D_96	16-bit Data Word 96	

The PROGP command instructs the PE to program one row of code memory (128 instruction words) to the specified memory address. Programming begins with the row address specified in the command. The destination address should be a multiple of 0x100.

The data to program the memory, located in command words, D_1 through D_96, must be arranged using the packed instruction word format illustrated in Figure 6-4.

After all data has been programmed to code memory, the PE verifies the programmed data against the data in the command.

Expected Response (2 words):

0x1500 0x0002

Note: Refer to Table 2-2 for code memory size information.

6.2.4.6 ERASEB Command

15	12	11	8	7		0
Орс	ode				Length	

Table 6-7 shows the description for the ${\tt ERASEB}$ command.

TABLE 6-7: COMMAND DESCRIPTION

Field	Description
Opcode	0x7
Length	0x1

The ERASEB command instructs the PE to perform a Chip Erase (i.e., erase all of the primary Flash memory, executive memory and code-protect bits).

Expected Response (2 words):

0x1700 0x0002

6.2.4.7 ERASEP Command

 15
 12
 11
 8
 7
 0

 Opcode
 Length

 NUM_PAGES
 Addr_MSB

 Addr_LS

Table 6-6 shows the description for the ERASEP command.

TABLE 6-8: COMMAND DESCRIPTION

Field	Description
Opcode	0x9
Length	0x3
NUM_PAGES	Up to 255
Addr_MSB	Most Significant Byte of the 24-bit address
Addr_LS	Least Significant 16 bits of the 24-bit address

The ERASEP command instructs the PE to Page Erase [NUM_PAGES] of code memory. The code memory must be erased at an "even" 1024 instruction words address boundary

Expected Response (2 words):

0x1900 0x0002 6.2.4.8 QVER Command

15	12	11		0
Opcode			Length	

Table 6-9 shows the description for the ${\tt QVER}$ command.

TABLE 6-9: COMMAND DESCRIPTION

Field	Description
Opcode	0xB
Length	0x1

The QVER command queries the version of the PE software stored in test memory. The "version.revision" information is returned in the response's QE_Code, using a single byte with the following format: main version in upper nibble and revision in the lower nibble (i.e., 0x23 means Version 2.3 of PE software).

Expected Response (2 words):

0x1BMN (where "MN" stands for version M.N) 0x0002

6.2.4.9 CRCP Command

 15
 12
 11
 8
 7
 0

 Opcode
 Length

 Reserved
 Addr_LSW

 Reserved
 Size_MSB

 Size LSW

Table 6-11 shows the description for the CRCP command.

TABLE 6-10: COMMAND DESCRIPTION

Field	Description
Opcode	0xC
Length	0x5
Addr_MSB	Most Significant Byte of 24-bit address
Addr_LSW	Least Significant 16 bits of 24-bit address
Size	Number of 24-bit locations (address range divided by 2)

The CRCP command performs a CRC-16 on the range of memory specified. This command can substitute for a full chip verify. Data is shifted in a packed method, as demonstrated in Figure 6-4: byte-wise, Least Significant Byte (LSB) first.

Example:

CRC-CCITT-16 with test data of "123456789" becomes 0x29B1

Expected Response (3 words):

QE_Code: 0x1C00 Length: 0x0003 CRC Value: 0xXXXX

6.2.4.10 QBLANK Command

 15
 12
 11
 0

 Opcode
 Length

 Reserved
 Size_MSB

 Size_LSW

 Reserved
 Addr_MSB

 Addr_LSW

Table 6-11 shows the description for the \mathtt{QBLANK} command.

TABLE 6-11: COMMAND DESCRIPTION

Field	Description
Opcode	0xE
Length	0x5
Size	Length of program memory to check (in 24-bit words) + Addr_MS
Addr_MSB	Most Significant Byte of the 24-bit address
Addr_LSW	Least Significant 16 bits of the 24-bit address

The QBLANK command queries the PE to determine if the contents of code memory are blank (contains all '1's). The size of code memory to check must be specified in the command.

The Blank Check for code memory begins at [Addr] and advances toward larger addresses for the specified number of instruction words.

<code>QBLANK</code> returns a QE_Code of 0xF0 if the specified code memory is blank; otherwise, <code>QBLANK</code> returns a QE Code of 0x0F.

Expected Response (2 words for blank device):

0x1EF0 0x0002

Expected Response (2 words for non-blank device):

0x1E0F 0x0002

Note: The QBLANK command does not check the system operation Configuration bits since these bits are not set to '1' when a Chip Erase is performed.

6.3 Programming Executive Responses

The PE sends a response to the programmer for each command that it receives. The response indicates if the command was processed correctly. It includes any required response data or error data.

The PE response set is shown in Table 6-12. This table contains the opcode, mnemonic and description for each response. The response format is described in **Section 6.3.1 "Response Format"**.

TABLE 6-12: PROGRAMMING EXECUTIVE RESPONSE OPCODES

Opcode	Mnemonic	Description
0x1	PASS	Command successfully processed.
0x2	FAIL	Command unsuccessfully processed.
0x3	NACK	Command not known.

6.3.1 RESPONSE FORMAT

All PE responses have a general format, consisting of a two-word header and any required data for the command.

Opcode	Last_Cmd	QE_Code			
	Lengtl	'n			
D_1 (if applicable)					
D_N (if applicable)					

Table 6-13 shows the description of the response format.

TABLE 6-13: RESPONSE FORMAT DESCRIPTION

Field	Description
Opcode	Response opcode.
Last_Cmd	Programmer command that generated the response.
QE_Code	Query code or error code.
Length	Response length in 16-bit words (includes 2 header words).
D_1	First 16-bit data word (if applicable).
D_N	Last 16-bit data word (if applicable).

6.3.1.1 Opcode Field

The opcode is a 4-bit field in the first word of the response. The opcode indicates how the command was processed (see Table 6-12). If the command was processed successfully, the response opcode is PASS. If there was an error in processing the command, the response opcode is FAIL and the QE_Code indicates the reason for the failure. If the command sent to the PE is not identified, the PE returns a NACK response.

6.3.1.2 Last Cmd Field

The Last_Cmd is a 4-bit field in the first word of the response and indicates the command that the PE processed. Since the PE can only process one command at a time, this field is technically not required. However, it can be used to verify that the PE correctly received the command that the programmer transmitted.

6.3.1.3 QE Code Field

The QE_Code is a byte in the first word of the response. This byte is used to return data for query commands and error codes for all other commands.

When the PE processes one of the two query commands (QBLANK or QVER), the returned opcode is always PASS and the QE_Code holds the query response data. The format of the QE_Code for both queries is shown in Table 6-14.

TABLE 6-14: QE_Code FOR QUERIES

Query	QE_Code
QBLANK	0x0F = Code memory is NOT blank 0xF0 = Code memory is blank
QVER	0xMN, where PE Software Version = M.N (i.e., 0x32 means Software Version 3.2).

When the PE processes any command other than a query, the QE_Code represents an error code. Supported error codes are shown in Table 6-15. If a command is successfully processed, the returned QE_Code is set to 0x0, which indicates that there is no error in the command processing. If the verify of the programming for the PROGW command fails, the QE_Code is set to 0x1. For all other PE errors, the QE_Code is 0x02.

TABLE 6-15: QE_CODE FOR NON-QUERY COMMANDS

QE_Code	Description
0x0	No error
0x1	Verify failed
0x2	Other error

6.3.1.4 Response Length

The response length indicates the length of the PE's response in 16-bit words. This field includes the 2 words of the response header.

With the exception of the response for the read commands, the length of each response is only 2 words.

The response to the READP commands uses the packed instruction word format described in **Section 6.2.2** "Packed Data Format". When reading an odd number of program memory words (N odd), the response to the READP command is (3 * (N + 1)/2 + 2) words. When reading an even number of program memory words (N even), the response to the READP command is (3 * N/2 + 2) words.

7.0 DUAL PARTITION FLASH PROGRAMMING CONSIDERATIONS

The PIC24FJ256GA412/GB412 family of devices supports a Single Partition Flash mode and two Dual Partition Flash modes. The Dual Partition modes allow the device to be programmed with two separate applications to facilitate bootloading or to allow an application to be programmed at run time without stalling the CPU.

The part's Partition Flash mode is determined by the BTMODE[1:0] bits in the FBOOT Configuration register (Table 7-1). The device will automatically check FBOOT on Reset and determine the appropriate Partition Flash mode.

TABLE 7-1: PARTITION FLASH MODE SELECT

FBOOT[1:0]	Partition Flash Mode				
00	Reserved				
01	Protected Dual Partition Flash mode				
10	Dual Partition Flash mode				
11	Single Partition Flash mode (default)				

7.1 Dual Partition Flash Memory Organization

In the Dual Partition Flash modes, the device's memory is divided evenly into two physical sections, known as Partition 1 and Partition 2. Each of these partitions contains its own program memory and Configuration Words. During program execution, the code on only one of these partitions is executed; this is the Active Partition. The other partition, or the Inactive Partition, is not used, but can be programmed.

The Active Partition is always mapped to logical address, 0x00 0000, while the Inactive Partition will always be mapped to logical address, 0x40 0000. Note that even when the code partitions are switched between Active and Inactive Partitions by the user, the address of the Active Partition will still be 0x00 0000, and the address of the Inactive Partition will still be at 0x40 0000.

The Boot Sequence Configuration Words (FBTSEQ) determine whether Partition 1 or Partition 2 will be active after Reset. If the part is operating in Dual Partition mode, the partition with the lower boot sequence number will operate as the Active Partition (FBTSEQ is unused in Single Partition mode). The partitions can be switched between Active and Inactive by reprogramming their boot sequence numbers, but the Active Partition will not change until a device Reset is performed. If both boot sequence numbers are the same, or if both are corrupted, the part will use Partition 1 as the Active Partition. If only one

boot sequence number is corrupted, the device will use the partition without a corrupted boot sequence number as the Active Partition.

The user can also change which partition is active at run time using the BOOTSWP instruction. Issuing a BOOTSWP instruction does not affect which partition will be the Active Partition after a Reset. Figure 7-1 demonstrates how the relationship between Partitions 1 and 2, shown in red and blue respectively, and the Active and Inactive Partitions are affected by reprogramming the boot sequence number or issuing a BOOTSWP instruction.

The P2ACTIV bit (NVMCON[10]) can be used to determine which physical partition is the Active Partition. If P2ACTIV = 1, Partition 2 is active; if P2ACTIV = 0, Partition 1 is active.

7.2 Erase Operations with Dual Partition Flash

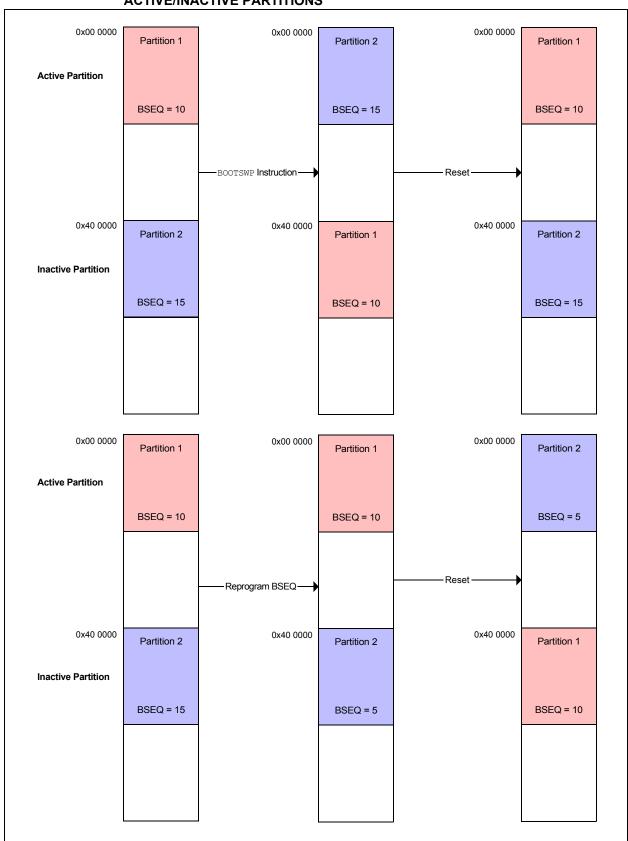
PIC24FJ256GA412/GB412 family devices support three erase operations: Chip Erase, Inactive Partition Erase and Page Erase.

A Chip Erase operation erases all of user memory, including the Flash Configuration Words and the FBOOT Configuration register. This resets the Partition Flash mode of the device to its default, Single Partition Flash mode. Chip Erase is not available during run-time operation.

An Inactive Partition Erase operation can be executed at run time from the Active Partition. It will erase all user memory and Flash Configuration Words in the Inactive Partition. Note that the Inactive Partition Erase command is only functional when the device is in one of the Dual Partition modes and permitted by the device's code protection settings.

Since the Flash Configuration Words reside in the last locations of user program space, they may be erased using a Chip Erase, an Inactive Partition Erase or a Page Erase that targets the last page of user Flash memory. Note that a Page Erase of the Configuration Words page may also erase the last lines of user code, which will need to be restored. See Section 3.7 "Writing Configuration Bits" for more information.

FIGURE 7-1: RELATIONSHIP BETWEEN PARTITIONS 1 AND 2 AND ACTIVE/INACTIVE PARTITIONS



7.3 Dual Partition Configuration Words

In Dual Partition modes, each partition has its own set of Flash Configuration Words. The full set of Configuration registers in the Active Partition is used to determine the device's configuration; the Configuration Words in the Inactive Partition are used to determine the device's configuration when that partition becomes active. However, some of the Configuration registers in the Inactive Partition (FSEC, FBSLIM and FSIGN) may be used to determine how the Active Partition is able or allowed to access the Inactive Partition.

7.4 Programming in Dual Partition Flash Mode

When programming a PIC24FJ256GA412/GB412 family device with multiple applications, the following sequence of steps is recommended to program the device correctly.

- 1. Perform a Chip Erase on the device.
- Program the FBOOT register to one of the Dual Partition modes, then reset the device to put it in Dual Partition Flash mode. At this point, the device's program memory is functionally divided into two partitions.
- 3. Program the first application (including its boot sequence number and Configuration Words) into the Active Partition at address, 0x00 0000.
- 4. Program the second application, its boot sequence number and its Configuration Words into the Inactive Partition at address, 0x40 0000.
- Finally, perform a device Reset. The Active/ Inactive Partitions may switch at this point, depending on the values that the user used for the boot sequence numbers for each application.

8.0 DEVICE ID

The Device ID region of memory can be used to determine variant and manufacturing information about the chip. This region of memory is read-only and can be read when code protection is enabled. The DEVID register (0xFF 0000) identifies the specific part number of the device, while DEVREV (0xFF 0002) shows the silicon revision level.

Table 8-1 lists the identification information for each device. Table 8-2 shows the Device ID registers and Table 8-3 describes the bit field of each register.

TABLE 8-1: DEVICE IDs

Device	DEVID
PIC24FJ64GA406	0x6100
PIC24FJ64GA410	0x6101
PIC24FJ64GA412	0x6102
PIC24FJ64GB406	0x6104
PIC24FJ64GB410	0x6105
PIC24FJ64GB412	0x6106
PIC24FJ128GA406	0x6108
PIC24FJ128GA410	0x6109
PIC24FJ128GA412	0x610A
PIC24FJ128GB406	0x610C
PIC24FJ128GB410	0x610D
PIC24FJ128GB412	0x610E
PIC24FJ256GA406	0x6110
PIC24FJ256GA410	0x6111
PIC24FJ256GA412	0x6112
PIC24FJ256GB406	0x6114
PIC24FJ256GB410	0x6115
PIC24FJ256GB412	0x6116

TABLE 8-2: PIC24FJ256GA412/GB412 FAMILY DEVICE ID REGISTERS

Address	Name	Bit															
Address	Name	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
0xFF 0000	DEVID		FAMID[7:0] DEV						[7:0]								
0xFF 0002	DEVREV		-							REV	[3:0]						

TABLE 8-3: DEVICE ID BIT FIELD DESCRIPTIONS

Bit Field	Register	Description	
FAMID[7:0]	DEVID	Encodes the family ID of the device.	
DEV[7:0] DEVID		Encodes the individual ID of the device.	
REV[3:0]	DEVREV	Encodes the sequential (numerical) revision identifier of the device.	

8.1 Unique Device Identifier (UDID)

All PIC24FJ256GA412/GB412 family devices are individually encoded during final manufacturing with a Unique Device Identifier or UDID. This feature allows for manufacturing traceability of Microchip Technology devices in applications where this is a requirement. It may also be used by the application manufacturer for any number of things that may require unique identification, such as:

- · Tracking the device
- · Unique serial number
- Unique security key

The UDID comprises five 24-bit program words. When taken together, these fields form a unique 120-bit identifier.

The UDID is stored in five read-only locations, located between 0x80 1308 and 0x80 1310 in the device configuration space. Table 8-4 lists the addresses of the Identifier Words and shows their contents.

TABLE 8-4: UDID ADDRESSES

UDID	Address	Description			
UDID1	0x80 1308	UDID Word 1			
UDID2	0x80 130A	UDID Word 2			
UDID3	0x80 130C	UDID Word 3			
UDID4	0x80 130E	UDID Word 4			
UDID5	0x80 1310	UDID Word 5			

9.0 CHECKSUM COMPUTATION

Checksums for devices are 16 bits in size. The checksum is calculated by summing the following:

- · Contents of code memory locations
- · Contents of Configuration Words

All memory locations, including Configuration Words, are summed by adding all three bytes of each memory address. The checksum is computed "bytewise", with the final result truncated to 16 bits. In the dsPIC33 architecture, each Flash memory address contains two bytes (if an even address) or one byte (if an odd address, since the upper byte is implemented and is always 0x00). When computing the checksum, both the upper and lower bytes of the word at a given address should be added to the running sum, separately as bytes, instead of as a single 16-bit word.

For example, in a program that contains two words with contents, such as:

Contents at address 0x0000 = 0xABCD

Contents at address 0x0001 = 0x00EF

The checksum over the 0x0000:0x0001 region is:

0xCD + 0xAB + 0xEF + 0x00 = 0x0267

These devices use a Dual Partition Flash memory, whose behavior is controlled by the FBOOT register. Table 9-2 shows a Single Partition set of checksums and Table 9-3 shows a Dual Partition set of checksums. The difference in the two is the inclusion of a second FSIGN register in Dual Partition mode and the values for FBOOT.

The CFGB block checksum is also a "bytewise" sum of all contents of the configuration block address region, and is computed identically to the PROG region with the exception that some Configuration registers may require certain bits to be AND masked out and excluded during the checksum computation.

TABLE 9-1: CONFIGURATION BIT MASKS

Device	Configuration Bit Mask						
Device	FSIGN	FPOR	FICD	FBOOTSEQ			
PIC24FJ256GA412/GB412 Family	0xFF 7FFF	0xFF FF7F	0xFF FFDF	0x00 0000			

TABLE 9-2: CHECKSUM COMPUTATION (SINGLE PARTITION)

Device	Read Code Protection	Checksum Computation		Value with 0xAA AAAA at 0x0 and Last Code Address
PIC24FJ256GB412	Disabled	PROG[0x0:0x2AF7F] + CFGB[0x2AF80:0x2AFFF]	0xF3E3 ⁽¹⁾	0xF1E5 ⁽¹⁾
F1C24FJ250GB412	Enabled	0	0x0000	0x0000
PIC24FJ128GB412	Disabled	PROG[0x0:0x1577F] + CFGB[0x15780:0x157FF]	0xF7E3 ⁽¹⁾	0xF5E5 ⁽¹⁾
FIG24FJ120GB412	Enabled	0	0x0000	0x0000
PIC24FJ64GB412	Disabled	PROG[0x0:0xAF7F] + CFGB[0xAF80:0xAFFF]	0xF3E3 ⁽¹⁾	0xF1E5 ⁽¹⁾
	Enabled	0	0x0000	0x0000

Legend: PROG[a:b] = Program memory byte sum of locations, a to b inclusive (all 3 bytes of code memory) CFGB[c:d] = Byte sum of locations, c to d inclusive (all 3 bytes of configuration memory), using any read masks shown in Table 9-1.

Note 1: For the checksum computation example, the Configuration bits are set to the default configuration values after erasing the part.

TABLE 9-3: CHECKSUM COMPUTATION (DUAL PARTITION)

Device	Read Code Protection	Checksum Computation	Erased Value	Value with 0xAA AAAA at 0x0 and Last Code Address
PIC24FJ256GB412	Disabled	PROG[0x0:0x1577F] + CFGB[0x15780:0x157FF] + PROG[0x40 0000:0x41 577F] + CFGB[0x41 5780:0x41 57FF]	0xEFC4 ⁽¹⁾	0xEBC8 ⁽¹⁾
	Enabled	0	0x0000	0x0000
PIC24FJ128GB412	Disabled	PROG[0x0:0xAA7F] + CFGB[0xAA80:0xABFF] + PROG[0x40 0000:0x40 AA7F] + CFGB[0x40 AA80:0x40 ABFF]	0xF3C4 ⁽¹⁾	0xEFC8 ⁽¹⁾
	Enabled	0	0x0000	0x0000
PIC24FJ64GB412	Disabled	PROG[0x0:0x577F] + CFGB[0x5780:0x57FF] + PROG[0x40 0000:0x40 577F] + CFGB[0x40 5780:0x40 57FF]	0xEFC4 ⁽¹⁾	0xEBC8 ⁽¹⁾
	Enabled	0	0x0000	0x0000

Legend: PROG[a:b] = Program memory byte sum of locations, a to b inclusive (all 3 bytes of code memory)

CFGB[c:d] = Byte sum of locations, c to d inclusive (all 3 bytes of configuration memory), using any read masks shown in Table 9-1.

Note 1: For the checksum computation example, the Configuration bits are set to the default configuration values after erasing the part and FBOOT is set to 0xFF FFFE (Dual Partition Flash mode).

10.0 AC/DC CHARACTERISTICS AND TIMING REQUIREMENTS

Table 10-1 lists the AC/DC characteristics and timing requirements.

TABLE 10-1: AC/DC CHARACTERISTICS AND TIMING REQUIREMENTS

Standard Operating Conditions

Operating Temperature: -40°C to +85°C. Programming at +25°C is recommended.

Symbol	Characteristic	Min.	Max.	Units	Conditions
1/22	Ourante Matterna Description			\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	One Note 4 and Note 0
		_		-	See Note 1 and Note 2
	,				See Note 2
	5 .		_		See Note 2
	-			ļ	See Note 2
ViH		_			See Note 2
Vol	Output Low Voltage		_	V	See Note 2
Vон	Output High Voltage	_	_	V	See Note 2
Сю	Capacitive Loading on I/O Pin (PGEDx)	_	_	pF	See Note 2
TPGC	Serial Clock (PGECx) Period (ICSP™)	200	_	ns	
TPGC	Serial Clock (PGECx) Period (Enhanced ICSP)	500	_	ns	
TPGCL	Serial Clock (PGECx) Low Time (ICSP)	80	_	ns	
TPGCL	Serial Clock (PGECx) Low Time (Enhanced ICSP)	200	_	ns	
Трдсн	Serial Clock (PGECx) High Time (ICSP)	80	_	ns	
TPGCH	Serial Clock (PGECx) High Time (Enhanced ICSP)	200	_	ns	
TSET1	Input Data Setup Time to Serial Clock ↓	15	_	ns	
THLD1	Input Data Hold Time from PGECx ↓	15	_	ns	
TDLY1	Delay Between 4-Bit Command and Command Operand	40	_	ns	
TDLY1A	Delay Between Command Operand and Next 4-Bit Command	40	_	ns	
TDLY2	Delay Between Last PGECx ↓ of Command to First PGECx ↑ of Read of Data Word	20	_	ns	
TSET2	VDD ↑ Setup Time to MCLR ↑	100	_	ns	
THLD2	Input Data Hold Time from MCLR ↑	50	_	ms	
TDLY3	Delay Between Last PGECx ↓ of Command Byte to PGEDx ↑ by PE	12	_	μS	
	VDD IDDP IPEAK VIL VIH VOL VOH CIO TPGC TPGC TPGCL TPGCL TPGCH TPGCH TDLY1 TDLY1 TDLY1 TDLY1A TDLY2 TSET2 THLD2	VDD Supply Voltage During Programming IDDP Supply Current During Programming IPEAK Instantaneous Peak Current During Start-up VIL Input Low Voltage VIH Input High Voltage VOL Output Low Voltage VOH Output High Voltage CIO Capacitive Loading on I/O Pin (PGEDx) TPGC Serial Clock (PGECx) Period (ICSP™) TPGC Serial Clock (PGECx) Period (Enhanced ICSP) TPGCL Serial Clock (PGECx) Low Time (ICSP) TPGCL Serial Clock (PGECx) Low Time (ICSP) TPGCH Serial Clock (PGECx) High Time (ICSP) TPGCH Serial Clock (PGECx) High Time (ICSP) TPGCH Serial Clock (PGECx) High Time (Enhanced ICSP) TSET1 Input Data Setup Time to Serial Clock ↓ THLD1 Input Data Hold Time from PGECx ↓ TDLY1 Delay Between 4-Bit Command and Command Operand TDLY1A Delay Between Command Operand and Next 4-Bit Command TDLY2 Delay Between Last PGECx ↓ of Command to First PGECx ↑ of Read of Data Word TSET2 VDD ↑ Setup Time to MCLR ↑ THLD2 Input Data Hold Time from MCLR ↑ TDLY3 Delay Between Last PGECx ↓ of Command TDLY4 Delay Between Last PGECx ↓ of Command	VDD Supply Voltage During Programming —	VDD Supply Voltage During Programming — IDDP Supply Current During Programming — IPEAK Instantaneous Peak Current During Start-up — VIL Input Low Voltage — VIH Input High Voltage — VOL Output Low Voltage — VOH Output High Voltage — CIO Capacitive Loading on I/O Pin (PGEDx) — TPGC Serial Clock (PGECx) Period (ICSP™) 200 TPGC Serial Clock (PGECx) Period (ICSP™) 200 TPGCL Serial Clock (PGECx) Period (ICSP) 80 TPGCL Serial Clock (PGECx) Low Time (ICSP) 80 TPGCL Serial Clock (PGECx) Low Time (ICSP) 80 TPGCH Serial Clock (PGECx) High Time (ICSP) 80 TPGCH Serial Clock (PGECx) High Time (ICSP) 80 TPGCH Serial Clock (PGECx) High Time (Enhanced ICSP) 15 TBET1 Input Data Hold Time from PGECx ↓ 15 TDLY1 Delay Between 4-Bit Command and Command And Command Operand 40 TDLY2 Delay Between Last PGECx ↓ of Command ICSP 100	VDD Supply Voltage During Programming — V IDDP Supply Current During Programming — — MA IPEAK Instantaneous Peak Current During Start-up — — — MA VIL Input Low Voltage — — V VIH Input High Voltage — — V VOL Output Low Voltage — — V VOH Output High Voltage — — V CIO Capacitive Loading on I/O Pin (PGEDx) — — pF TPGC Serial Clock (PGECx) Period (ICSP™) 200 — ns TPGC Serial Clock (PGECx) Period (ICSP™) 200 — ns TPGCL Serial Clock (PGECx) Low Time (ICSP) 80 — ns TPGCL Serial Clock (PGECx) Low Time (ICSP) 80 — ns TPGCH Serial Clock (PGECx) High Time (ICSP) 80 — ns TPGCH Serial Clock (PGECx) High Time (ICSP) 80 — ns TPGCH Serial Clock (PGECx) High Time (ICSP) 80

Note 1: VDD must also be supplied to the AVDD pins during programming. AVDD and AVss should always be within ±0.3V of VDD and Vss, respectively.

^{2:} Time depends on the FRC accuracy and the value of the FRC Oscillator Tuning register. Refer to the "**Electrical Characteristics**" chapter in the specific device data sheet.

^{3:} This time applies to Program Memory Words, Configuration Words and User ID Words.

TABLE 10-1: AC/DC CHARACTERISTICS AND TIMING REQUIREMENTS (CONTINUED)

Standard Operating Conditions

Operating Temperature: -40°C to +85°C. Programming at +25°C is recommended.

Param. No.	Symbol	Characteristic		Max.	Units	Conditions
P9A	TDLY4	PE Command Processing Time	10	_	μS	
P9B	TDLY5	Delay Between PGEDx ↓ by PE to PGEDx, Released by PE	15	23	μS	
P10	TDLY6	PGECx Low Time After Programming	400	_	ns	
P11	TDLY7	Chip Erase Time	18	27	ms	
P12	TDLY8	Page Erase Time	18	27	ms	See Note 2
P13	TDLY9	Double-Word Programming Time	18	_	μS	See Note 2 and Note 3
P14	TR	MCLR Rise Time to Enter ICSP mode	_	1.0	μS	
P15	TVALID	Data Out Valid from PGECx ↑	10	_	ns	
P16	TDLY10	Delay Between Last PGECx ↓ and MCLR ↓	0	_	s	
P17	THLD3	MCLR ↓ to VDD ↓	100	_	ns	
P18	TKEY1	Delay from First MCLR ↓ to First PGECx ↑ for Key Sequence on PGEDx	1	_	ms	
P19	TKEY2	Delay from Last PGECx ↓ for Key Sequence on PGEDx to Second MCLR ↑	25	_	ns	
P21	TMCLRH	MCLR High Time	_	500	μS	

Note 1: VDD must also be supplied to the AVDD pins during programming. AVDD and AVSS should always be within ±0.3V of VDD and VSS, respectively.

^{2:} Time depends on the FRC accuracy and the value of the FRC Oscillator Tuning register. Refer to the **"Electrical Characteristics"** chapter in the specific device data sheet.

^{3:} This time applies to Program Memory Words, Configuration Words and User ID Words.

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APPENDIX A: SPI PORT SCANNING SOFTWARE ROUTINE

EXAMPLE A-1: SPI PORT SCANNING SOFTWARE CODE EXAMPLE

```
* © 2016 Microchip Technology Inc.
* FileName: spi search.s
* Dependencies: none
* Processor: PIC24
* Compiler: XC16
* TDE: MPLAB® X
* Description: This file performs a search of the correct
* PGEC/PGED port and connect SPI2 slave to it.
*************************
******************
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```

EXAMPLE A-1: SPI PORT SCANNING SOFTWARE CODE EXAMPLE (CONTINUED)

```
.include "xc.inc"
.global _sd_Port_Search
.pushsection .text, code
:-----
; Constants
:-----
.equ
     PPS SPI2 DATA SCK SDI INPUT, #RPINR22 ; PPS register for data and sck input
     PPS PGEC1 PGED1 INPUT,
                         #0x0100
.equ
     PPS PGEC2 PGED2 INPUT,
                        #0x0607
.equ
     PPS PGEC3 PGED3 INPUT,
                        #0x121C
.equ
.equ
    PORT FOUND, #1
    PORT NOT FOUND, #0
.equ
;-----
; Returns port number found on w0, 0 if no port found
; It will also leave SPI2 connected to the identified port
_sd_Port_Search:
                   ; Must unlock PPS to scan PGED/PGEC ports
  rcall PPS_Unlock
rcall SPI_Init
                         ; SPI1 as master and SPI2 as slave for loopback test
  rcall ICSP Scan1
  cp w0, #PORT_FOUND
bra z, port_search_found
  rcall ICSP_Scan2
       w0, #PORT_FOUND
  ср
  bra
        z, port_search_found
  rcall ICSP Scan3
  ср
         w0, #PORT_FOUND
       z, port_search_found
  bra
port search not found:
  bclr SPI1CON1L, #15 ; disable SPI1
                          ; return 0
  clr
         w0
  return
port search found:
  bclr SPI1CON1L, #15 ; disable SPI1
         w1, w0
  mov.
                          ; return port number
  return
```

EXAMPLE A-1: SPI PORT SCANNING SOFTWARE CODE EXAMPLE (CONTINUED)

```
PPS_Unlock:
                                                                                                                                        ; place zero in w0 to unlock PPS
; OSCCONL (low byte) unlock sequence
; Preparing unlock sequence
                                           #0, w0
                 mov
               mov #0, wo
mov #0SCCONL, w1
mov #0x46, w2
mov #0x57, w3
                                                                                                                                                             ; Preparing unlock sequence
                mov #0x57, w3
                mov.b w2, [w1]
                                                                                                                                                              ; Write 0x46
                mov.b w3, [w1]
                                                                                                                                                               ; Write 0x9A
                mov.b w0, [w1]
                                                                                                                                                                 ; unlock PPS (IOLOCK bit = 0)
                 return
; Initialize SPI1 as master and SPI2 as slave % \left\{ 1\right\} =\left\{ 1
; for loopback test on each programming port
SPI Init:
                                                                                                                                                  ; clear SPI1BRGL
; clear SPI1CON1H
               clr SPI1BRGL
                 clr SPI1CON1H
                                                                                                                                                              ; clear SPI1CON1L
                 clr SPI1CON1L
                                                   #0x8120, w0
                 mov
                                                                                                                                                               ; set SPIEN, CKE and MSTEN (master)
                                             w0, SPI1CON1L
                clr SPI2CON1H
                                                                                                                                                                ; clear SPI2CON1H
                clr SPI2CON1L
                                                                                                                                                               ; clear SPI2CON1L
                                        #0x0100, w0
                                                                                                                                                                ; set CKE (slave)
                mov w0, SPI2CON1L
                 return
; Returns PORT FOUND, or PORT NOT FOUND on w0
; Returns port number on w1
:-----
ICSP Scan1:
               mov #PPS PGEC1 PGED1 INPUT, w0
                                         w0, PPS SPI2 DATA SCK SDI INPUT
                 rcall _sd_Loopback_Test
                 mov
                                             #1, w1
                 return
:-----
ICSP Scan2:
                                         #PPS PGEC2 PGED2 INPUT, w0
                 mov w0, PPS SPI2 DATA SCK SDI INPUT
                 rcall _sd_Loopback_Test
                 mov
                                              #2, w1
                  return
```

EXAMPLE A-1: SPI PORT SCANNING SOFTWARE CODE EXAMPLE (CONTINUED)

```
ICSP Scan3:
       #PPS_PGEC3_PGED3_INPUT, w0
  mov
       w0, PPS_SPI2_DATA_SCK_SDI_INPUT
  mov
  rcall _sd_Loopback_Test
  mov #3, w1
  return
; Returns PORT FOUND, or PORT NOT FOUND on w0
:-----
_sd_Loopback_Test:
  bset SPI2CON1L, #15 ; enable SPI2
                     ; 0xa5 pattern
  mov #0x00a5, w0
  mov
       w0, SPI1BUFL
                          ; send
loopback wait data:
  btss SPI1STATL, #0
                     ; wait for the data
       loopback_wait_data
  bra
  mov SPI1BUFL, w1
  mov SPI2BUFL, w1 ; read data bclr SPI2CON1L, #15 ; disable SPI2
        w0, w1
  ср
       z, loopback found
  bra
  mov
       #PORT NOT FOUND, w0
  return
loopback_found:
  mov #PORT_FOUND, w0
  return
.popsection
```

APPENDIX B: REVISION HISTORY

Revision A (February 2015)

Original version of this document.

Revision B (May 2016)

Updated the Dual Partition Flash modes for PIC24FJ64GX4XX in Table 2-3.

Updated the description for WDTCLK<1:0> in Table 2-4.

Changed values for FPOR and FICD in Table 9-1 and updated Table 9-2.

Revision C (January 2017)

Updated existing Pin Diagrams and added additional Pin Diagrams in Figure 2-3 through Figure 2-8.

Replaced the previous Table 2-4 with a new table, titled: Table 2-4: Configuration Registers Map.

Added Section 8.1 "Unique Device Identifier (UDID)" and replaced Section 9.0 "Checksum Computation" with new text.

Added Appendix A: "SPI Port Scanning Software Routine".

Revision D (March 2019)

Updated Section 4.4 "Entering Enhanced ICSP Mode" and Section 8.1 "Unique Device Identifier (UDID)".

Updated Figure 4-3.

Updated Table 2-4 and Table 8-4.

Added notes to all Pin Diagrams.

OTES:			

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China - Guangzhou Tel: 86-20-8755-8029

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China - Nanjing Tel: 86-25-8473-2460

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China - Shanghai Tel: 86-21-3326-8000

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China - Shenzhen Tel: 86-755-8864-2200

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Tel: 86-592-2388138

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